TPS746-Q1 1-A LDO With Power-Good in Small Wettable Flank WSON Packages

1 Features

- AEC-Q100 qualified for automotive applications:
  - Temperature grade 1: –40°C to +125°C, T_A
- Device operating junction temperature range: –40°C to +150°C
- Package:
  - 2-mm × 2-mm wettable flank WSON
  - 3-mm × 3-mm wettable flank WSON (preview)
- Input voltage range: 1.5 V to 6.0 V
- Output voltage range:
  - Fixed option: 0.65 V to 5.0 V
  - Adjustable option: 0.55 V to 5.5 V
- High PSRR: 38 dB at 100 kHz
- Output accuracy: ±0.85% typical, ±1.5% maximum
- Power-good output options:
  - Open-drain or push-pull
- Ultra-low dropout:
  - 265 mV (max) at 1 A (3.3 V_{OUT})
- Stable with a 1-µF or larger capacitor
- Low I_Q: 25 µA (typical)
- Active output discharge
- Low thermal resistance:
  - DRV (6-pin WSON), $R_{\theta JA}$ = 80.3°C/W
  - DRB (8-pin WSON), $R_{\theta JA}$ = 62.0°C/W (preview)

2 Applications

- Automotive head units
- Front and rear cameras
- Automotive cluster displays
- Telematics control units
- Medium, short range radar

3 Description

The TPS746-Q1 is a 1-A ultra-low-dropout regulator (LDO) with power-good functionality. This device is available in a small 6-pin, 2-mm × 2-mm and a small 8-pin, 3-mm × 3-mm WSON package with wettable flanks to facilitate optical inspection. The TPS746-Q1 consumes low quiescent current and provides fast line and load transient performance.

The TPS746-Q1 is a flexible device for post-regulation by supporting an input voltage range from 1.5 V to 6.0 V and an externally adjustable output range of 0.55 V to 5.5 V. The device also features fixed output voltages for powering common voltage rails.

The TPS746-Q1 has a power-good (PG) output that monitors the voltage at the feedback pin to indicate the status of the output voltage. The EN input and PG output can be used for sequencing multiple power supplies in the system.

The TPS746-Q1 is stable with small ceramic output capacitors, allowing for a small overall solution size. A precision band-gap and error amplifier provides high accuracy of ±0.85% (max) at 25°C and ±1.5% (max) over temperature. This device includes integrated thermal shutdown, current limit, and undervoltage lockout (UVLO) features. The TPS746-Q1 has an internal foldback current limit that helps reduce the thermal dissipation during short-circuit events.

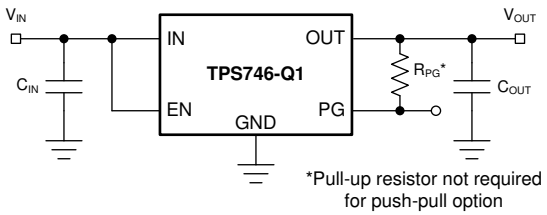
Device Information(1)

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TPS746-Q1	Wettable flank WSON (6)	2.00 mm × 2.00 mm
	Wettable flank WSON (8)(2)	3.00 mm × 3.00 mm

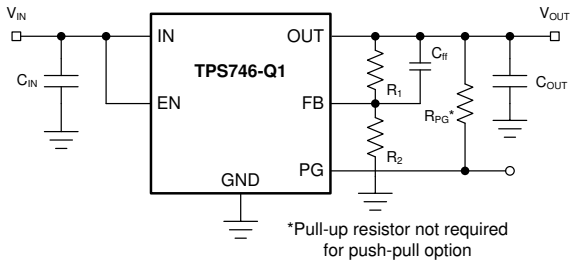
(1) For all available packages, see the orderable addendum at the end of the data sheet.

(2) Preview package.

Typical Application: Fixed Voltage Version



Typical Application: Adjustable Voltage Version



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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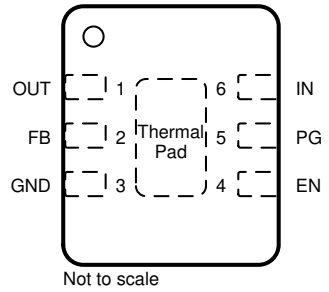
4 Revision History

Changes from Original (June 2019) to Revision A	Page
• Changed document status from APL to production data	1

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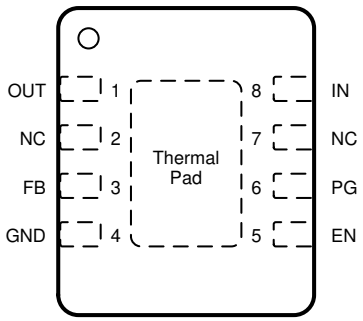
5 Pin Configuration and Functions

DRV Package
6-Pin Adjustable WSON
Top View



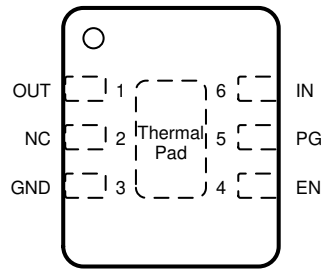
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DRB Package (Preview)
8-Pin Adjustable WSON
Top View



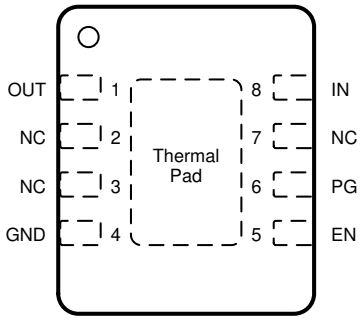
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DRV Package
6-Pin Fixed WSON
Top View



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DRB Package (Preview)
8-Pin Fixed WSON
Top View



Not to scale

Pin Functions

PIN					I/O	DESCRIPTION
NAME	DRV (Fixed)	DRV (Adjust)	DRB (Fixed)	DRB (Adjust)		
EN	4	4	5	5	Input	Enable pin. Drive EN greater than $V_{EN(HI)}$ to turn on the regulator. Drive EN less than $V_{EN(LO)}$ to put the low-dropout regulator (LDO) into shutdown mode.
FB	—	2	—	3	—	This pin is used as an input to the control loop error amplifier and is used to set the output voltage of the LDO.
GND	3	3	4	4	—	Ground pin.
IN	6	6	8	8	Input	Input pin. For best transient response and to minimize input impedance, use the recommended value or larger ceramic capacitor from IN to ground as listed in the *Recommended Operating Conditions* table and the *Input and Output Capacitor Selection* section. Place the input capacitor as close to the output of the device as possible.
NC	2	—	2, 3, 7	2, 7	—	No internal connection. Ground this pin for better thermal performance.
OUT	1	1	1	1	Output	Regulated output voltage pin. A capacitor is required from OUT to ground for stability. For best transient response, use the nominal recommended value or larger ceramic capacitor from OUT to ground; see the *Recommended Operating Conditions* table and the *Input and Output Capacitor Selection* section. Place the output capacitor as close to the output of the device as possible.

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Pin Functions (continued)

PIN					I/O	DESCRIPTION
NAME	DRV (Fixed)	DRV (Adjust)	DRB (Fixed)	DRB (Adjust)		
PG	5	5	6	6	Output	Power-good output. Available in open-drain and push-pull topologies. A pullup resistor is required for the open-drain version. For the open-drain version, if the power-good functionality is not being used, ground this pin or leave floating. For the push-pull version, if the power-good functionality is not being used, leave this pin floating.
Thermal Pad					—	The thermal pad is electrically connected to the GND node. Connect to the GND plane for improved thermal performance.

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
Voltage	Supply, V_{IN}	–0.3	6.5	V
	Enable, V_{EN}	–0.3	6.5	
	Feedback, V_{FB}	–0.3	2.0	
	Power-good, V_{PG}	–0.3	6.5	
	Output, V_{OUT}	–0.3	V_{IN} + 0.3(2)	
Current	Output, I_{OUT}	Internally limited		
	Power-good, I_{PG}		±10	mA
Temperature	Operating junction, T_J	–40	150	°C
	Storage, T_{stg}	–65	150	

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The absolute maximum rating is V_{IN} + 0.3 V or 6.0 V, whichever is smaller.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per AEC Q100-002(1)	±2000	V
		Charged-device model (CDM), per AEC Q100-011, corner pins	±750	
		Charged-device model (CDM), per AEC Q100-011, other pins	±500	

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	NOM	MAX	UNIT
V_{IN}	Input voltage		1.5		6.0	V
V_{OUT}	Output voltage	Adjustable version	0.55		5.5	V
		Fixed version	0.65		5.0	
I_{OUT}	Output current		0		1	A
C_{IN}	Input capacitor		1			µF
C_{OUT}	Output capacitor(1)		1		220	µF
C_{FF}	Feed-forward capacitor			10		nF
V_{EN}	Enable voltage		0		6.0	V
f_{EN}	Enable toggle frequency				10	kHz
V_{PG}	PG voltage		0		6.0	V
T_J	Junction temperature		–40		150	°C

(1) Minimum derated capacitance of 0.47 µF is required for stability

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6.4 Thermal Information

THERMAL METRIC[1]		TPS746-Q1		UNIT
		DRV (WSON)	DRB (WSON)[2]	
		6 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	80.3	62.0	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	98.7	73.1	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	44.8	35.1	°C/W
ψ_{JT}	Junction-to-top characterization parameter	6.1	6.3	°C/W
ψ_{JB}	Junction-to-board characterization parameter	45.0	35.1	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	20.8	18.2	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.
(2) Preview package.

6.5 Electrical Characteristics

at operating temperature range (T_J = –40°C to +150°C), V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 1.5 V (whichever is greater), I_{OUT} = 1 mA, V_{EN} = V_{IN}, and C_{IN} = C_{OUT} = 1 µF (unless otherwise noted); all typical values at T_J = 25°C

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_{FB}	Feedback voltage				0.55		V
	Output accuracy[1]	T_J = 25°C		–0.85%		0.85%	
		-40°C ≤ T_J ≤ 85°C		–1.00%		1.00%	
		-40°C ≤ T_J ≤ 150°C		–1.50%		1.50%	
	Line regulation	$V_{OUT(NOM)}$ + 0.5 V[2] ≤ V_{IN} ≤ 6.0 V			2	7.5	mV
	Load regulation	0.1 mA ≤ I_{OUT} ≤ 1 A, V_{IN} ≥ 2.0 V			0.030		V/A
I_{GND}	Ground current	I_{OUT} = 0 mA	T_J = 25°C		25	32	µA
			-40°C ≤ T_J ≤ 150°C		25	36	
I_{SHDN}	Shutdown current	V_{EN} ≤ 0.3 V, 1.5 V ≤ V_{IN} ≤ 6.0 V	-40°C ≤ T_J ≤ 125°C		0.1	1	µA
			-40°C ≤ T_J ≤ 150°C		0.1	1.55	
I_{FB}	Feedback pin current	Adjustable only			0.01	0.1	µA
I_{CL}	Output current limit	$V_{OUT(NOM)}$ < 1 V, V_{OUT} = $V_{OUT(NOM)}$ - 0.2 V, V_{IN} = 2.0 V		1.22	1.5	1.83	A
		$V_{OUT(NOM)}$ ≥ 1 V, V_{OUT} = $V_{OUT(NOM)}$ × 0.85, V_{IN} = $V_{OUT(NOM)}$ + 1.0 V					
I_{SC}	Short-circuit current limit	V_{OUT} = 0 V	$V_{OUT(NOM)}$ < 1 V, V_{IN} = 2.0 V		680	850	mA
			$V_{OUT(NOM)}$ ≥ 1 V, V_{IN} = $V_{OUT(NOM)}$ + 1.0 V				
V_{DO}	Dropout voltage	I_{OUT} = 1 A, V_{OUT} = 0.95 x $V_{OUT(NOM)}$	0.65 V ≤ V_{OUT} < 0.8 V[3]		895	1090	mV
			0.8 V ≤ V_{OUT} < 0.9 V		765	960	
			0.9 V ≤ V_{OUT} < 1.0 V		700	890	
			1.0 V ≤ V_{OUT} < 1.2 V		600	790	
			1.2 V ≤ V_{OUT} < 1.5 V		465	625	
			1.5 V ≤ V_{OUT} < 1.8 V		335	480	
			1.8 V ≤ V_{OUT} < 2.5 V		265	400	
			2.5 V ≤ V_{OUT} < 3.3 V		195	310	
			3.3 V ≤ V_{OUT} < 5.5 V		160	265	
PSRR	Power-supply rejection ratio	V_{OUT} = 1.8 V, V_{IN} = 2.8 V, I_{OUT} = 1 A, C_{OUT} = 2.2 µF	f = 1 kHz		53		dB
			f = 100 kHz		38		
			f = 1 MHz		30		
V_N	Output noise voltage	BW = 10 Hz to 100 kHz, V_{OUT} = 0.9 V, V_{IN} = 1.9 V			53		μV_{RMS}
V_{UVLO}	Undervoltage lockout	V_{IN} rising		1.21	1.33	1.47	V
		V_{IN} falling		1.17	1.29	1.42	

(1) When the device is connected to external feedback resistors at the FB pin, external resistor tolerances are not included.
(2) V_{IN} = 1.5V for V_{OUT} < 1.0 V
(3) Dropout is not tested for nominal output voltages below 0.65 V since the input voltage may be below UVLO.

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Electrical Characteristics (continued)

at operating temperature range (T_J = –40°C to +150°C), V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 1.5 V (whichever is greater), I_{OUT} = 1 mA, V_{EN} = V_{IN}, and C_{IN} = C_{OUT} = 1 µF (unless otherwise noted); all typical values at T_J = 25°C

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{UVLO,HYST}$	Undervoltage lockout hysteresis	V_{IN} hysteresis		40		mV
t_{STR}	Startup time	From EN low-to-high transition to V_{OUT} = $V_{OUT(NOM)}$ x 95%		500	650	µs
V_{HI}	EN pin high voltage (enabled)		1.0			V
V_{LO}	EN pin low voltage (disabled)				0.3	V
I_{EN}	Enable pin current	V_{IN} = V_{EN} = 6.0 V		10		nA
$R_{PULLDOWN}$	Pulldown resistance	V_{IN} = 6.0 V		95		Ω
PG_{HTH}	PG high threshold	V_{OUT} increasing	89	92	96	$\%V_{OUT}$
PG_{LTH}	PG low threshold	V_{OUT} decreasing	86	90	93	$\%V_{OUT}$
PG_{HYST}	PG hysteresis			2		$\%V_{OUT}$
$V_{OL(PG)}$	PG pin low-level output voltage	V_{OUT} ≥ 1.5 V, I_{SINK} = 1 mA			300	mV
		V_{OUT} ≥ 2.75 V, I_{SINK} = 2 mA				
$V_{OH(PG)}$	PG pin high-level output voltage(4)	V_{OUT} ≥ 1.0 V, I_{SOURCE} = 0.04 mA	0.8 × V_{OUT}			V
		V_{OUT} ≥ 1.4 V, I_{SOURCE} = 0.2 mA				
		V_{OUT} ≥ 2.5 V, I_{SOURCE} = 0.5 mA				
		V_{OUT} ≥ 4.5 V, I_{SOURCE} = 1.0 mA				
$I_{lkg(PG)}$	PG pin leakage current(5)	V_{OUT} > PG_{HTH}, V_{PG} = 6.0 V		7	50	nA
T_{SD}	Thermal shutdown	Shutdown, temperature increasing		170		°C
		Reset, temperature decreasing		155		

(4) Push-pull version only. The push-pull option is supported only for V_{OUT} ≥ 1.0 V.
(5) Open-drain version only.

6.6 Timing Requirements

			MIN	NOM	MAX	UNIT
t_{PGDH}	PG delay time rising, time from 92% V_{OUT} to 20% of PG(1)		135	165	178	µs
		'B' version(2)	4.5	5	5.5	ms
t_{PGDL}	PG delay time falling, time from 90% V_{OUT} to 80% of PG(1)		1.5	7	10	µs

(1) Output overdrive = 10%.
(2) See the Device Nomenclature table for more information on available PG timings.

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6.7 Typical Characteristics

at operating temperature range T_J = 25°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 1.5 V (whichever is greater), I_{OUT} = 1 mA, V_{EN} = V_{IN}, and C_{IN} = C_{OUT} = 1 µF (unless otherwise noted)

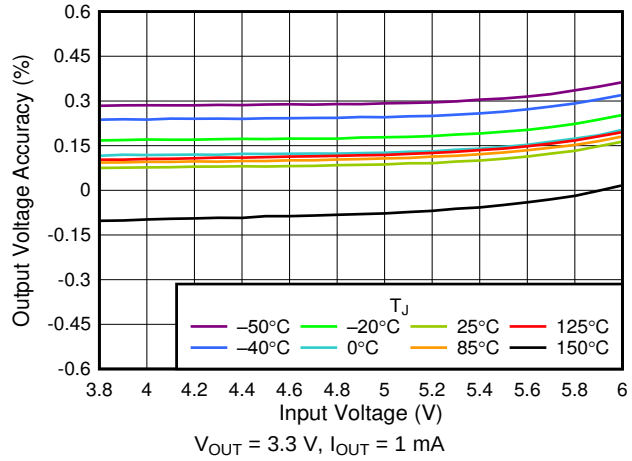


Figure 1. 3.3-V Line Regulation vs V_{IN}

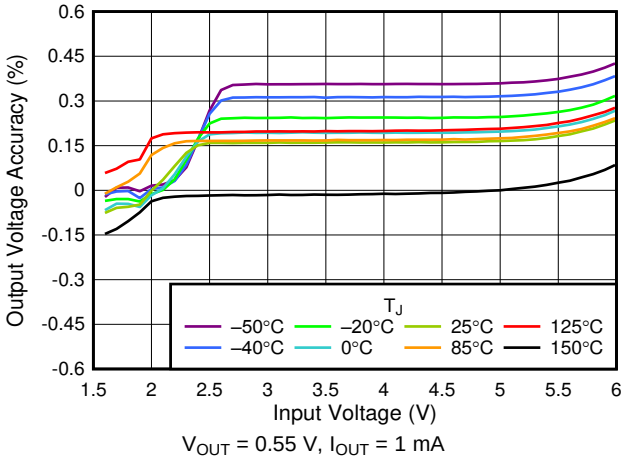


Figure 2. 0.55-V Line Regulation vs V_{IN}

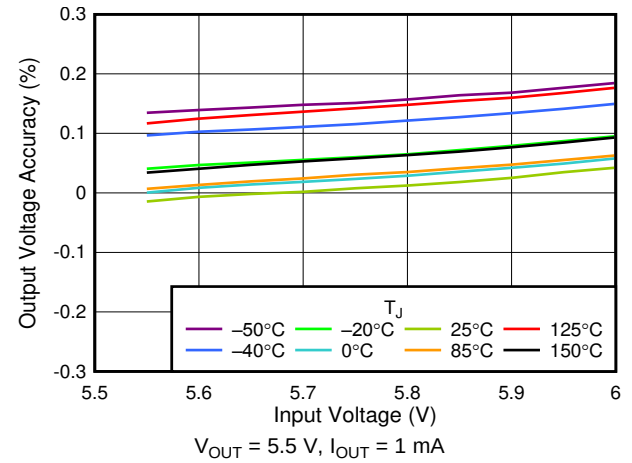


Figure 3. 5.5-V Line Regulation vs V_{IN}

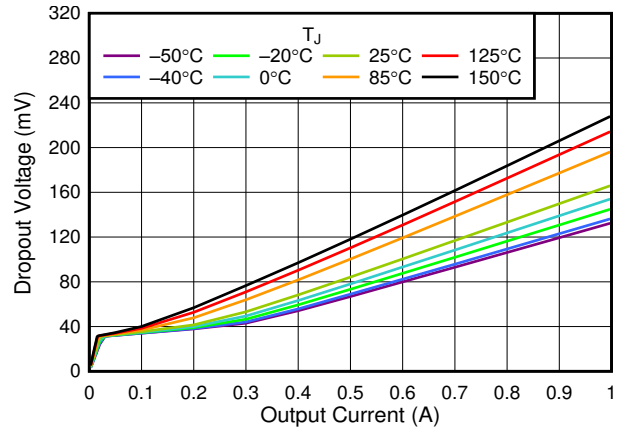


Figure 4. 3.3-V Dropout Voltage vs I_{OUT}

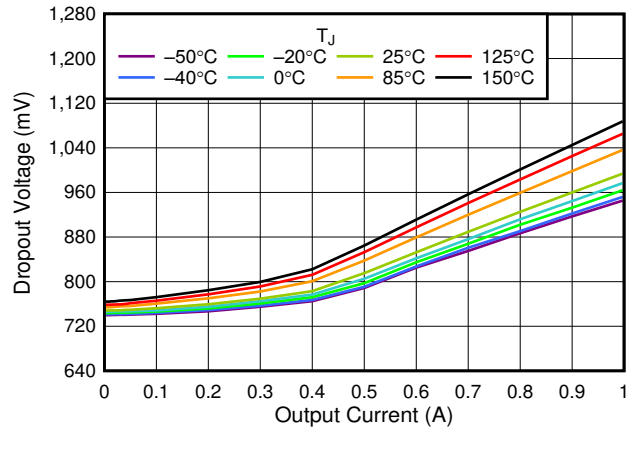


Figure 5. 0.55-V Dropout Voltage vs I_{OUT}

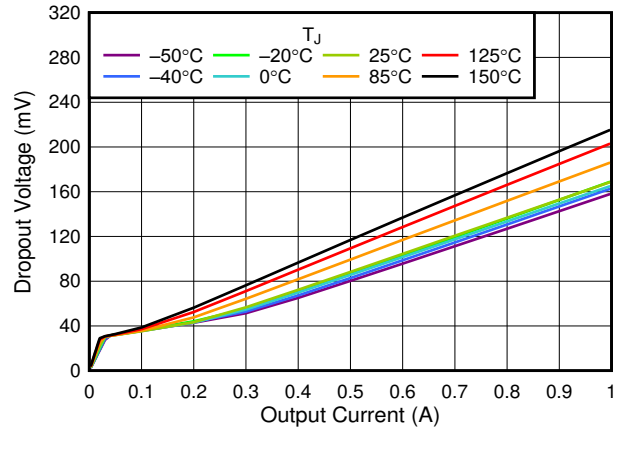


Figure 6. 5.5-V Dropout Voltage vs I_{OUT}

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Typical Characteristics (continued)

at operating temperature range T_J = 25°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 1.5 V (whichever is greater), I_{OUT} = 1 mA, V_{EN} = V_{IN}, and C_{IN} = C_{OUT} = 1 µF (unless otherwise noted)

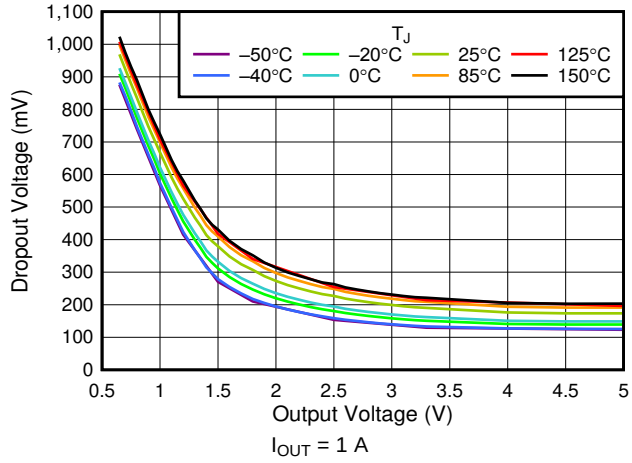


Figure 7. V_{DO} vs V_{OUT}

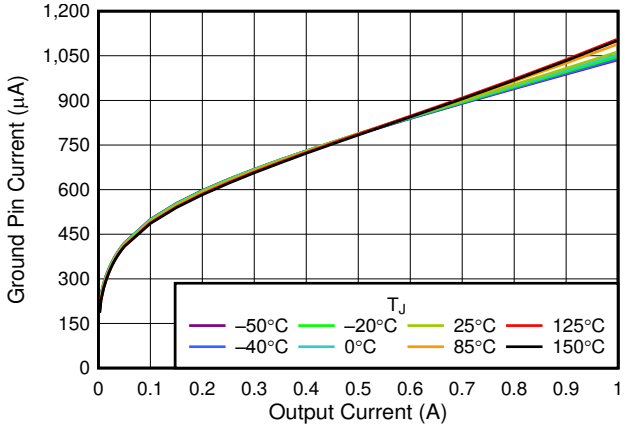


Figure 8. I_{GND} vs I_{OUT}

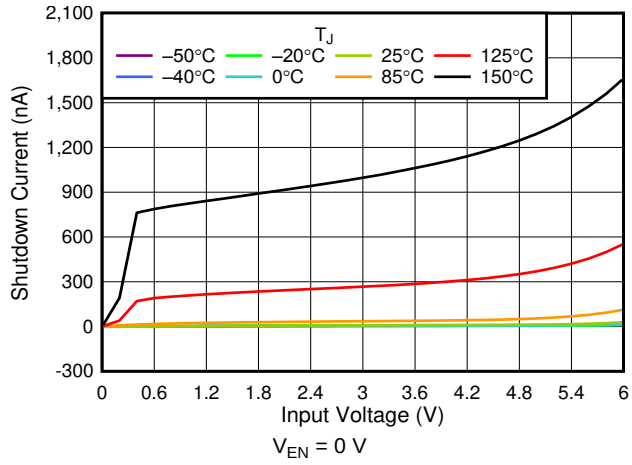


Figure 9. I_{SHDN} vs V_{IN}

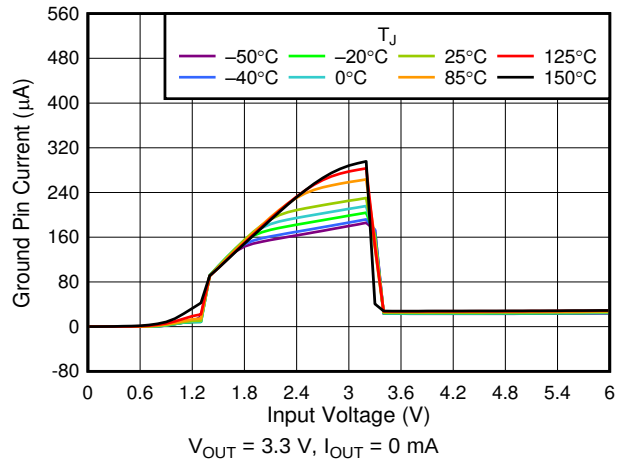


Figure 10. I_{GND} vs V_{IN}

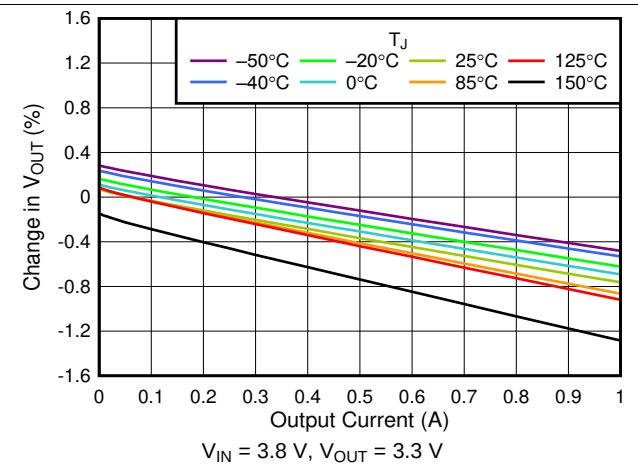


Figure 11. 3.3-V Load Regulation vs I_{OUT}

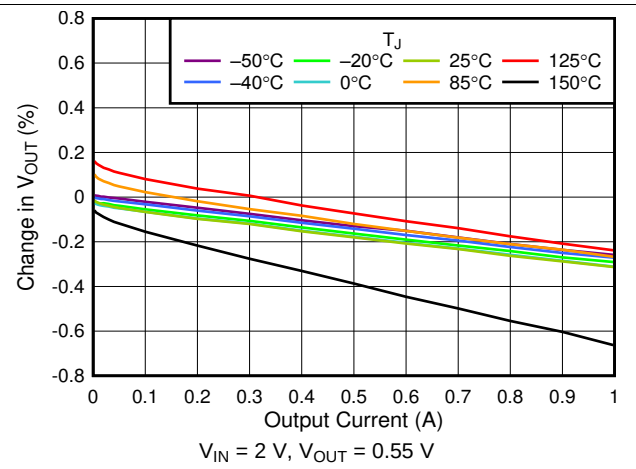


Figure 12. 0.55-V Load Regulation vs I_{OUT}

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Typical Characteristics (continued)

at operating temperature range T_J = 25°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 1.5 V (whichever is greater), I_{OUT} = 1 mA, V_{EN} = V_{IN}, and C_{IN} = C_{OUT} = 1 µF (unless otherwise noted)

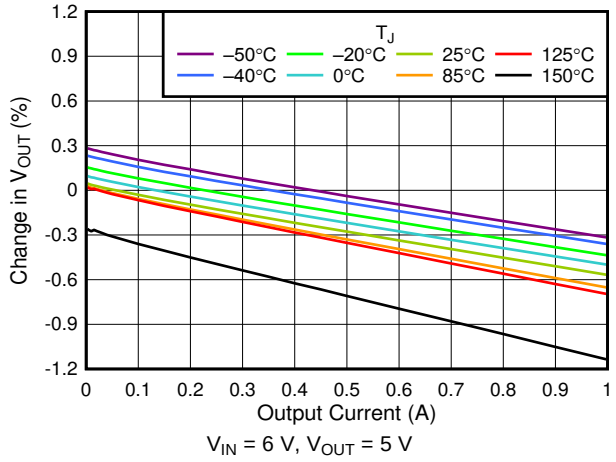


Figure 13. 5-V Load Regulation vs I_{OUT}

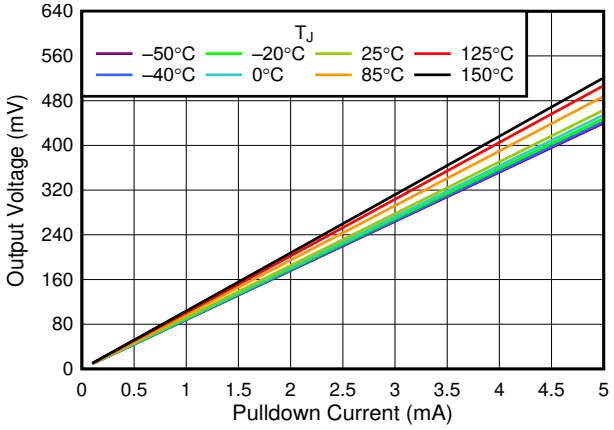


Figure 14. V_{OUT} vs I_{OUT} Pulldown Resistor

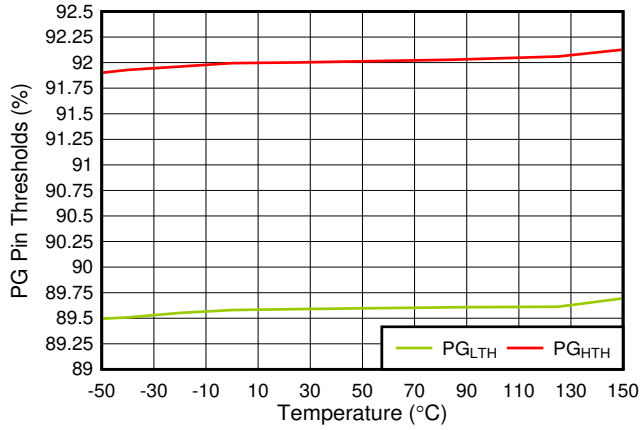


Figure 15. PG_{LTH} and PG_{HTH} vs Temperature

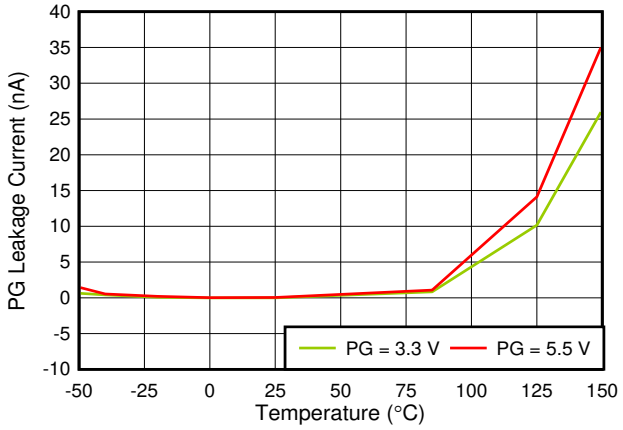


Figure 16. $I_{lkg(PG)}$ vs Temperature and PG Pin Voltage

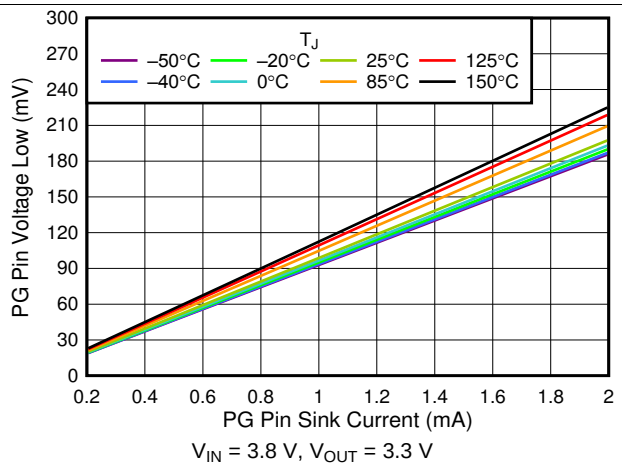


Figure 17. $V_{OL(PG)}$ vs PG Pin Sink Current

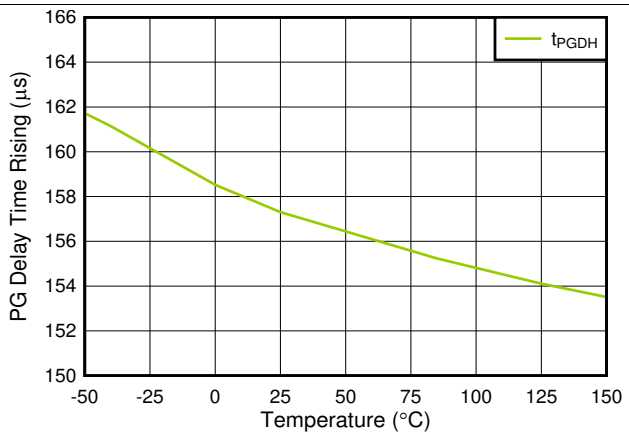


Figure 18. t_{PGDH} vs Temperature

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Typical Characteristics (continued)

at operating temperature range T_J = 25°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 1.5 V (whichever is greater), I_{OUT} = 1 mA, V_{EN} = V_{IN}, and C_{IN} = C_{OUT} = 1 µF (unless otherwise noted)

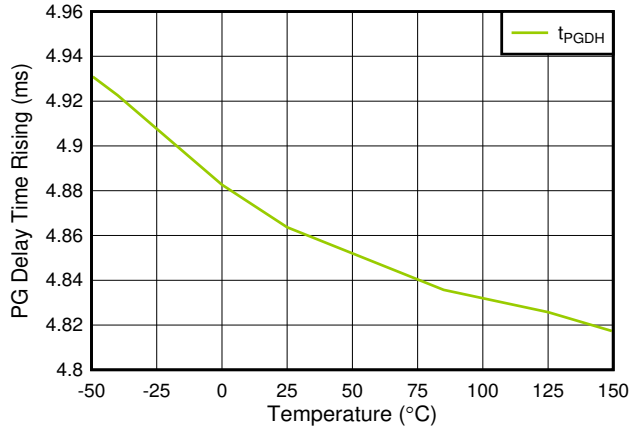


Figure 19. t_{PGDH} vs Temperature (For TPS746B Only)

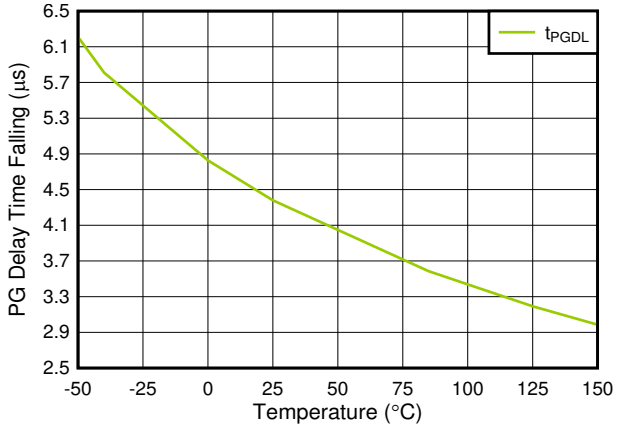


Figure 20. t_{PGDL} vs Temperature

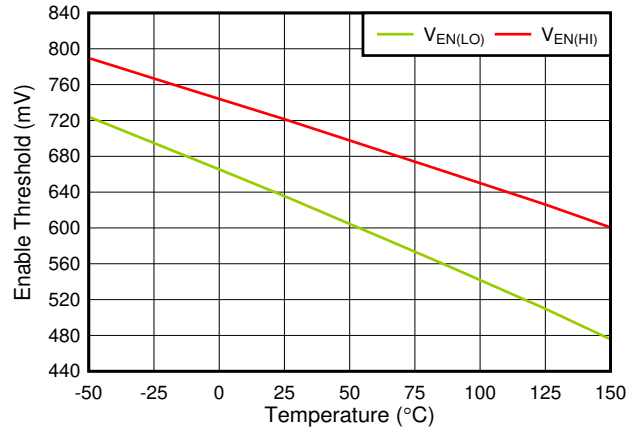


Figure 21. $V_{EN(HI)}$ and $V_{EN(LO)}$ vs Temperature

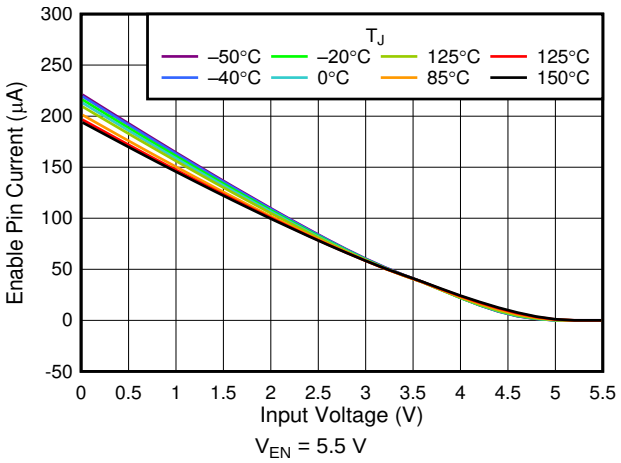


Figure 22. I_{EN} vs V_{IN}

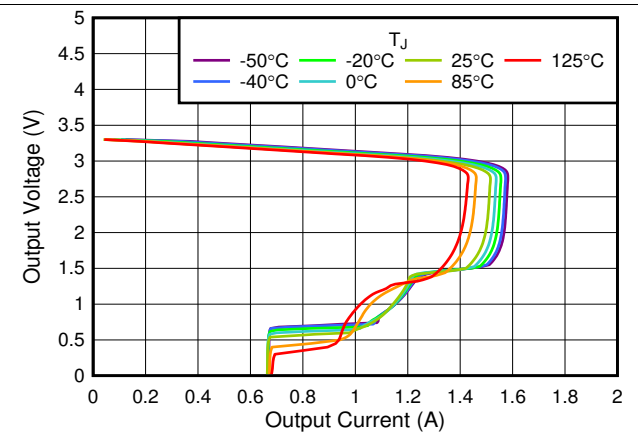


Figure 23. 3.3-V Foldback Current Limit vs I_{OUT}

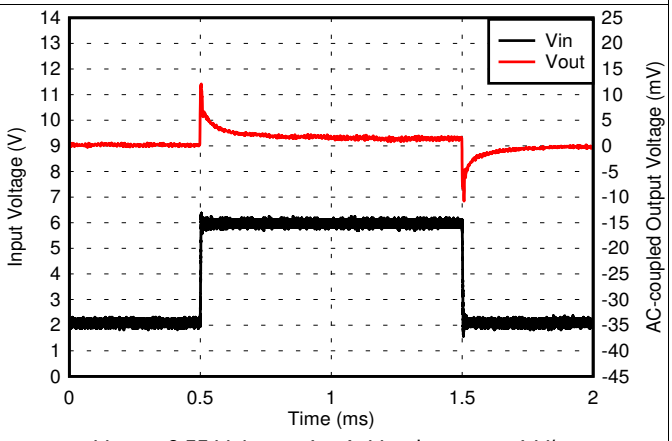
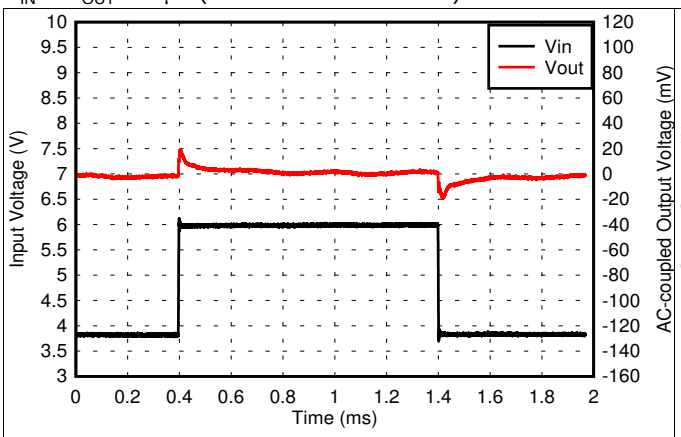


Figure 24. 0.55-V Line Transient

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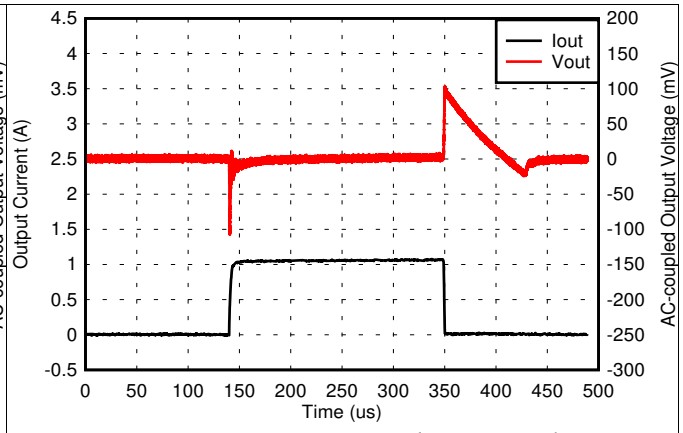
Typical Characteristics (continued)

at operating temperature range T_J = 25°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 1.5 V (whichever is greater), I_{OUT} = 1 mA, V_{EN} = V_{IN}, and C_{IN} = C_{OUT} = 1 µF (unless otherwise noted)



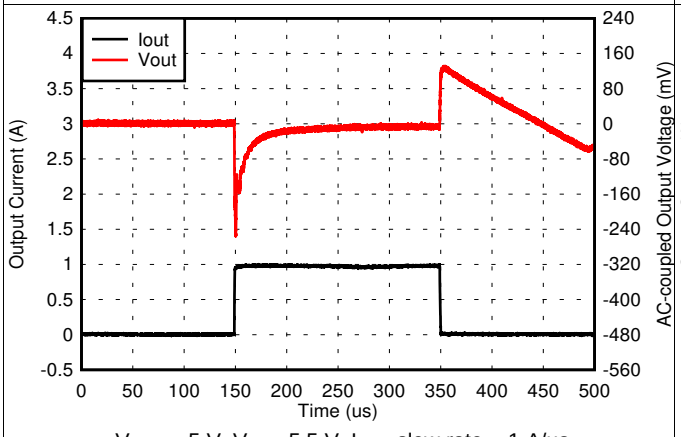
V_{OUT} = 3.3 V, I_{OUT} = 1 mA, V_{IN} slew rate = 1 V/µs

Figure 25. 3.3-V Line Transient



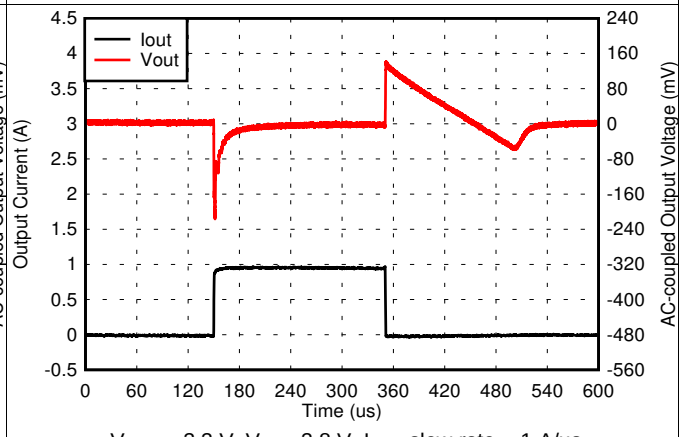
V_{OUT} = 0.55 V, V_{IN} = 2 V, I_{OUT} slew rate = 1 A/µs

Figure 26. 1-mA to 1-A Load Transient (0.55 V)



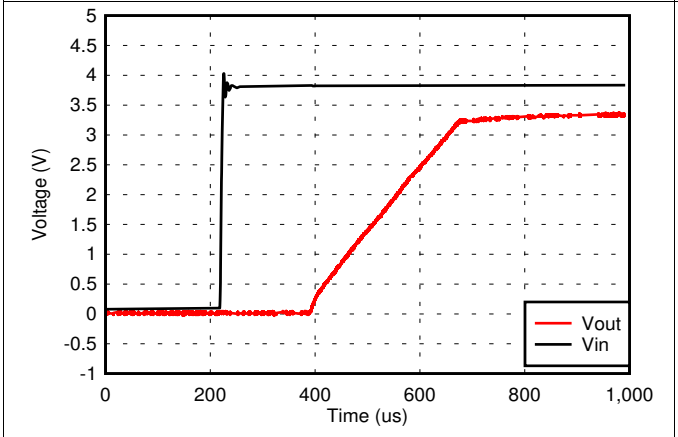
V_{OUT} = 5 V, V_{IN} = 5.5 V, I_{OUT} slew rate = 1 A/µs

Figure 27. 1-mA to 1-A Load Transient (5 V)



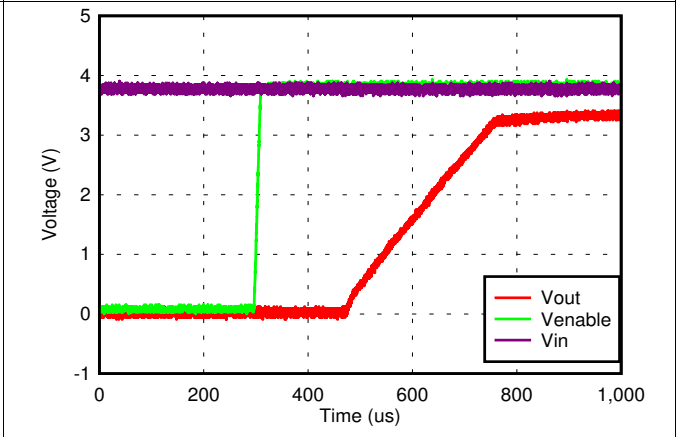
V_{OUT} = 3.3 V, V_{IN} = 3.8 V, I_{OUT} slew rate = 1 A/µs

Figure 28. 1-mA to 1-A Load Transient (3.3 V)



V_{IN} = 3.8 V, V_{OUT} = 3.3 V, I_{OUT} = 1 mA

Figure 29. V_{IN} Power-Up



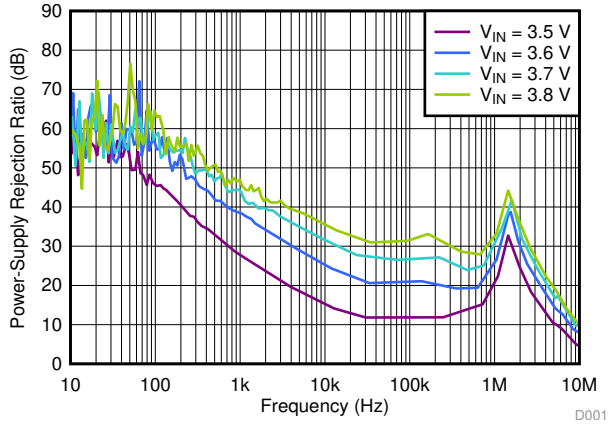
V_{IN} = 3.8 V, V_{OUT} = 3.3 V, I_{OUT} = 1 mA

Figure 30. Startup With EN

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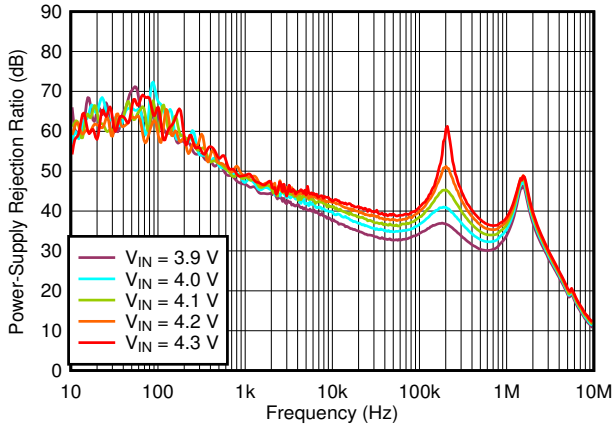
Typical Characteristics (continued)

at operating temperature range T_J = 25°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 1.5 V (whichever is greater), I_{OUT} = 1 mA, V_{EN} = V_{IN}, and C_{IN} = C_{OUT} = 1 µF (unless otherwise noted)



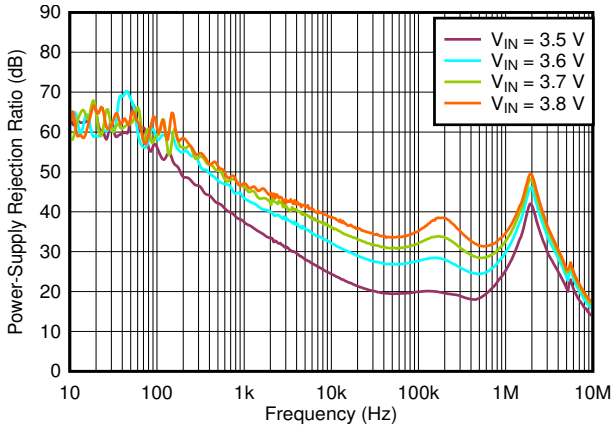
V_{OUT} = 3.3 V, I_{OUT} = 500 mA, C_{OUT} = 2.2 µF

Figure 31. PSRR vs Frequency and V_{IN}



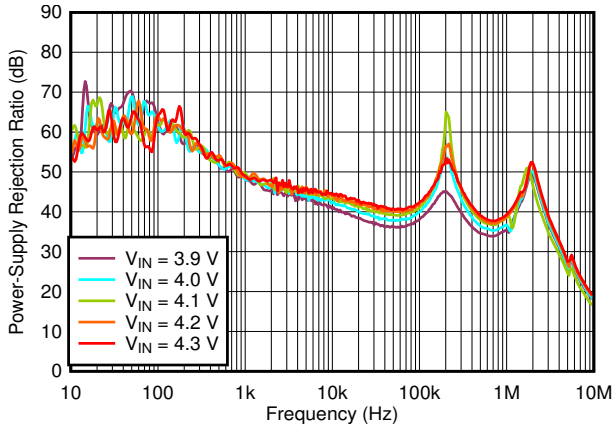
V_{OUT} = 3.3 V, I_{OUT} = 500 mA, C_{OUT} = 2.2 µF

Figure 32. PSRR vs Frequency and V_{IN}



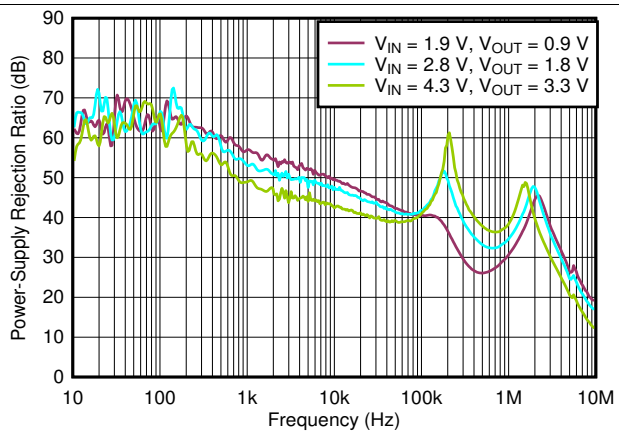
V_{OUT} = 3.3 V, I_{OUT} = 250 mA, C_{OUT} = 2.2 µF

Figure 33. PSRR vs Frequency and V_{IN}



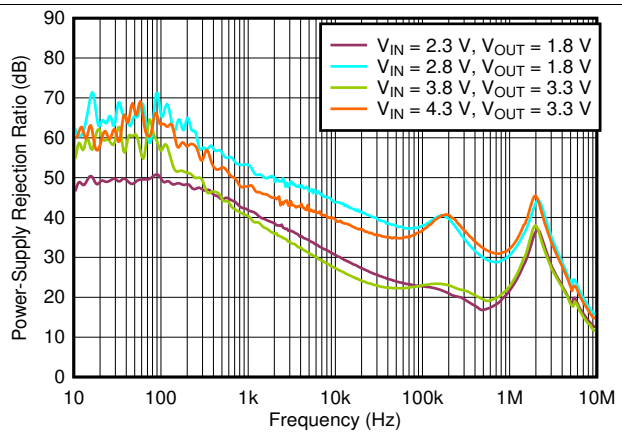
V_{OUT} = 3.3 V, I_{OUT} = 250 mA, C_{OUT} = 2.2 µF

Figure 34. PSRR vs Frequency and V_{IN}



I_{OUT} = 500 mA, C_{OUT} = 2.2 µF

Figure 35. PSRR vs Frequency



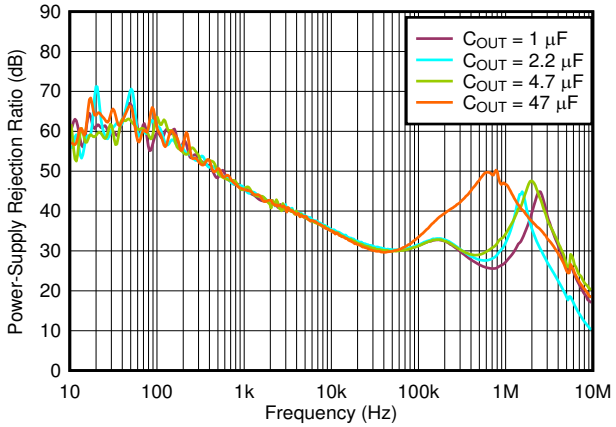
I_{OUT} = 1 A, C_{OUT} = 2.2 µF

Figure 36. PSRR vs Frequency

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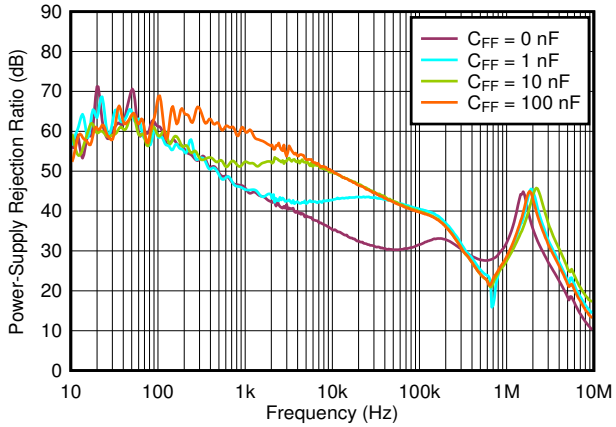
Typical Characteristics (continued)

at operating temperature range T_J = 25°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 1.5 V (whichever is greater), I_{OUT} = 1 mA, V_{EN} = V_{IN}, and C_{IN} = C_{OUT} = 1 µF (unless otherwise noted)



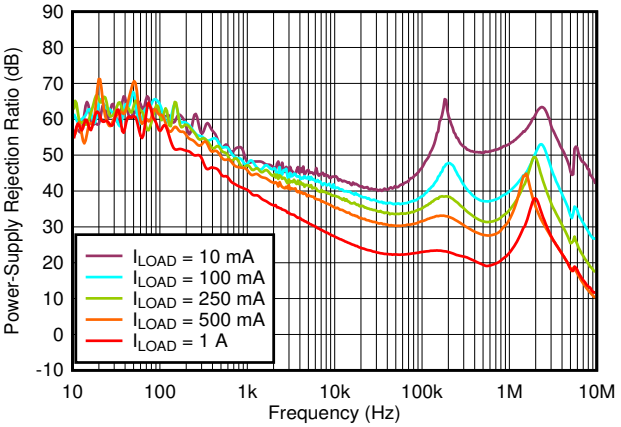
V_{IN} = 3.8 V, V_{OUT} = 3.3 V, I_{OUT} = 500 mA

Figure 37. PSRR vs Frequency and C_{OUT}



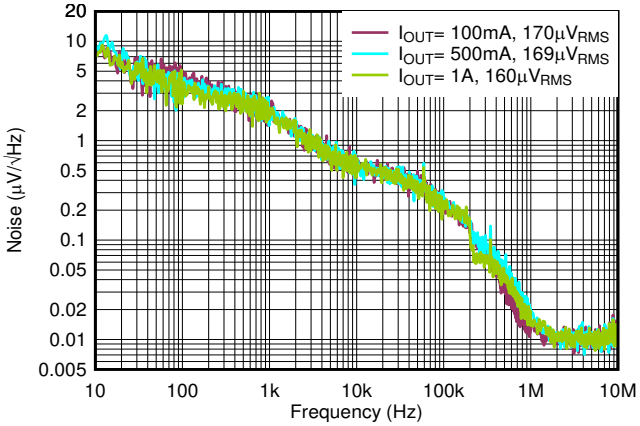
V_{IN} = 3.8 V, V_{OUT} = 3.3 V, I_{OUT} = 500 mA

Figure 38. PSRR vs Frequency and C_{FF}



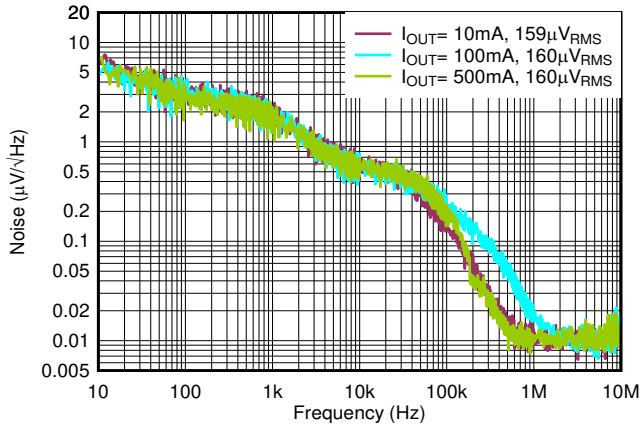
V_{IN} = 3.8 V, V_{OUT} = 3.3 V, C_{OUT} = 2.2 µF

Figure 39. PSRR vs Frequency and I_{LOAD}



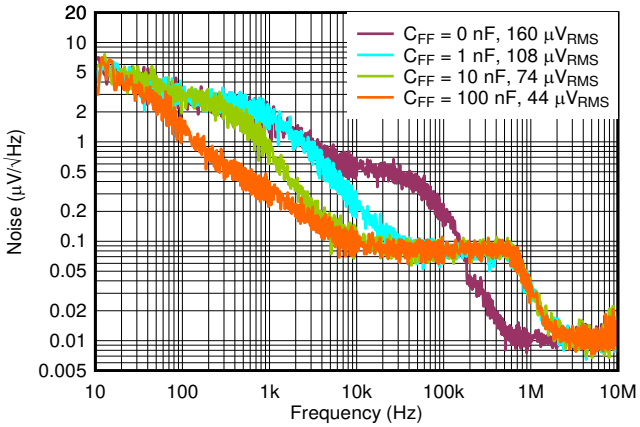
V_{IN} = 3.8 V, V_{OUT} = 3.3 V, C_{OUT} = 4.7 µF,
V_{RMS} BW = 10 Hz to 100 kHz

Figure 40. Output Spectral Noise Density vs Frequency and I_{OUT}



V_{IN} = 3.8 V, V_{OUT} = 3.3 V, C_{OUT} = 2.2 µF,
V_{RMS} BW = 10 Hz to 100 kHz

Figure 41. Output Spectral Noise Density vs Frequency and I_{OUT}



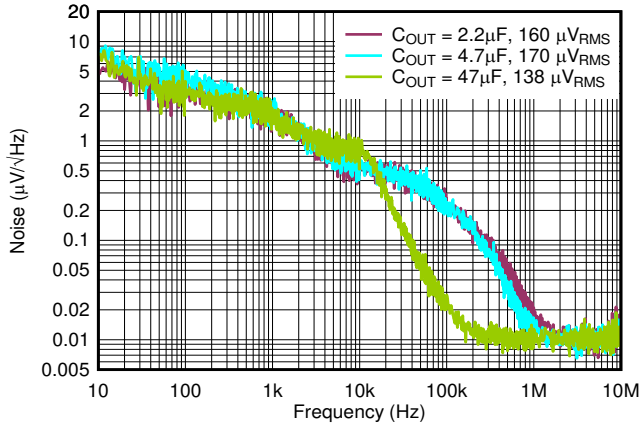
V_{IN} = 3.8 V, V_{OUT} = 3.3 V, I_{OUT} = 500 mA, C_{OUT} = 2.2 µF,
V_{RMS} BW = 10 Hz to 100 kHz

Figure 42. Output Spectral Noise Density vs Frequency and C_{FF}

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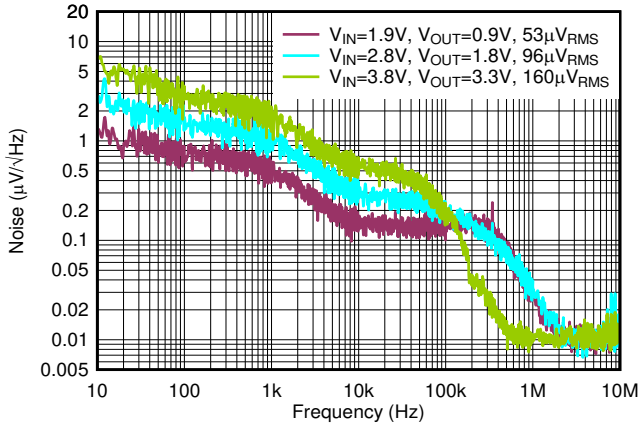
Typical Characteristics (continued)

at operating temperature range T_J = 25°C, V_{IN} = $V_{OUT(NOM)}$ + 0.5 V or 1.5 V (whichever is greater), I_{OUT} = 1 mA, V_{EN} = V_{IN}, and C_{IN} = C_{OUT} = 1 µF (unless otherwise noted)



V_{IN} = 3.8 V, V_{OUT} = 3.3 V, I_{OUT} = 100 mA, C_{FF} = 0 µF, V_{RMS} BW = 10 Hz to 100 kHz

Figure 43. Output Spectral Noise Density vs Frequency and C_{OUT}



I_{OUT} = 500 mA, C_{OUT} = 2.2 µF, V_{RMS} BW = 10 Hz to 100 kHz

Figure 44. Output Spectral Noise Density vs Frequency

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7 Detailed Description

7.1 Overview

The TPS746-Q1 is a low-dropout regulator (LDO) that consumes low quiescent current and delivers excellent line and load transient performance. These characteristics, combined with low noise and good PSRR with low dropout voltage, make this device ideal for portable consumer applications.

This regulator offers foldback current limit, shutdown, and thermal protection. The operating junction temperature for this device is –40°C to +150°C.

7.2 Functional Block Diagrams

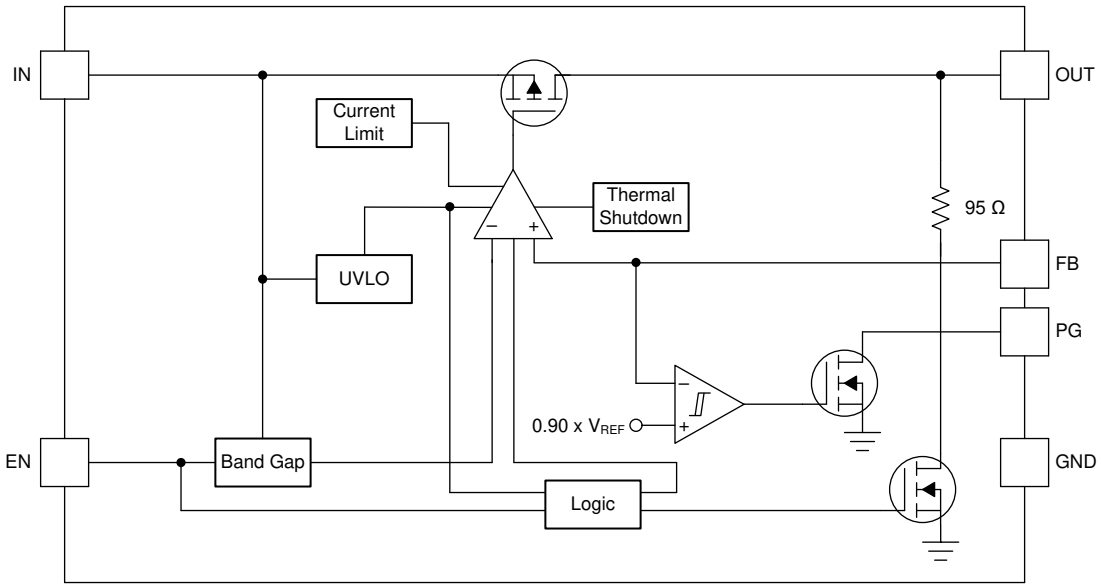


Figure 45. Adjustable Version With Open-Drain Power-Good

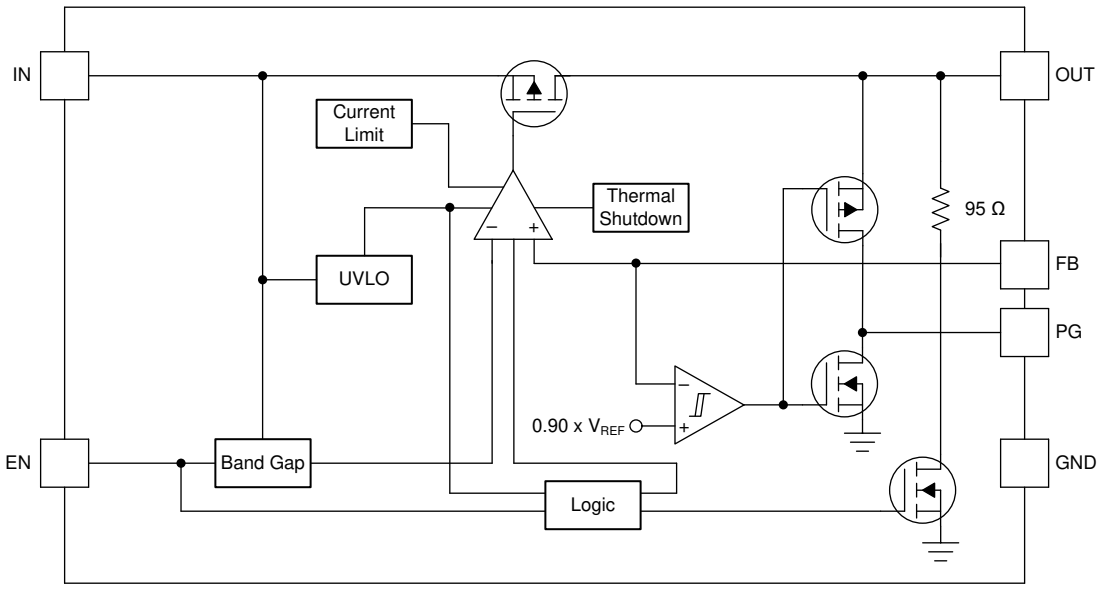


Figure 46. Adjustable Version With Push-Pull Power-Good

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Functional Block Diagrams (continued)

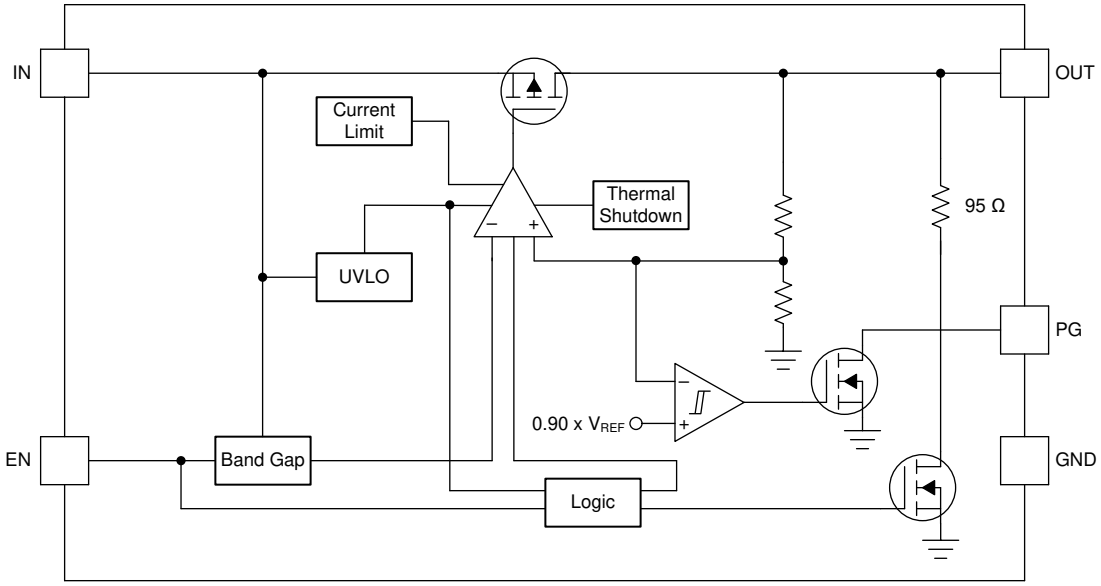


Figure 47. Fixed Voltage Version With Open-Drain Power-Good

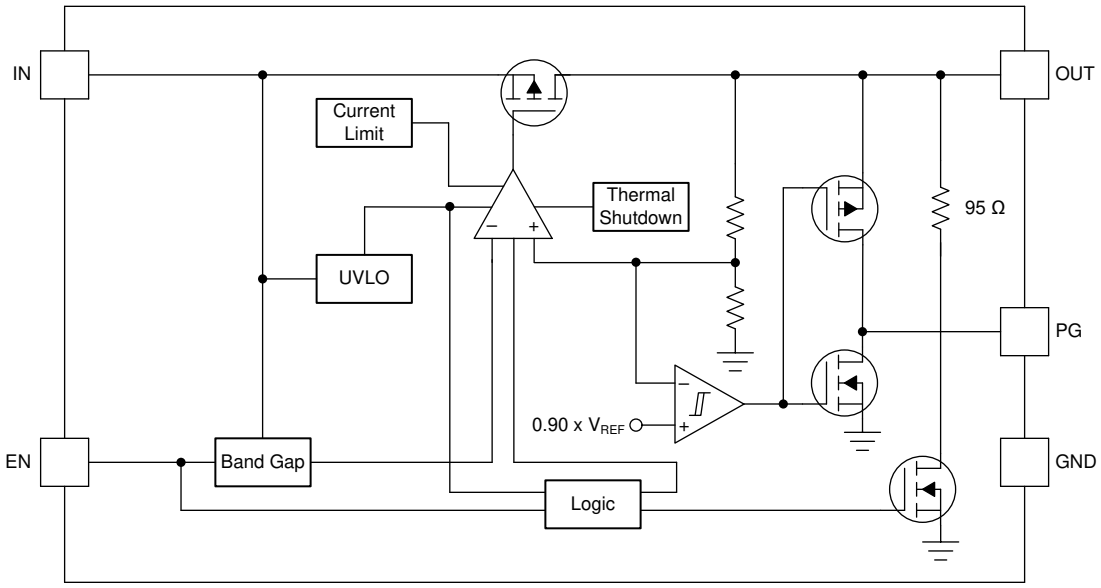


Figure 48. Fixed Voltage Version With Push-Pull Power-Good

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7.3 Feature Description

7.3.1 Undervoltage Lockout (UVLO)

The TPS746-Q1 uses an undervoltage lockout (UVLO) circuit that disables the output until the input voltage is greater than the rising UVLO voltage (V_{UVLO}). This circuit ensures that the device does not exhibit any unpredictable behavior when the supply voltage is lower than the operational range of the internal circuitry. When V_{IN} is less than V_{UVLO}, the output is connected to ground with a pulldown resistor ($R_{PULLDOWN}$).

7.3.2 Shutdown

The enable pin (EN) is active high. Enable the device by forcing the EN pin to exceed $V_{EN(HI)}$. Turn off the device by forcing the EN pin to drop below $V_{EN(LO)}$. If shutdown capability is not required, connect EN to IN.

The TPS746-Q1 has an internal pulldown MOSFET that connects an $R_{PULLDOWN}$ resistor to ground when the device is disabled. The discharge time after disabling depends on the output capacitance (C_{OUT}) and the load resistance (R_L) in parallel with the pulldown resistor ($R_{PULLDOWN}$). Equation 1 calculates the time constant:

$$\tau = (R_{PULLDOWN} \times R_L) / (R_{PULLDOWN} + R_L) \quad (1)$$

7.3.3 Foldback Current Limit

The device has an internal current limit circuit that protects the regulator during transient high-load current faults or shorting events. The current limit is a hybrid brickwall-foldback scheme. The current limit transitions from a brickwall scheme to a foldback scheme at the foldback voltage ($V_{FOLDBACK}$). In a high-load current fault with the output voltage above $V_{FOLDBACK}$, the brickwall scheme limits the output current to the current limit (I_{CL}). When the voltage drops below $V_{FOLDBACK}$, a foldback current limit activates that scales back the current as the output voltage approaches GND. When the output is shorted, the device supplies a typical current called the short-circuit current limit (I_{SC}). I_{CL} and I_{SC} are listed in the *Electrical Characteristics* table.

For this device, $V_{FOLDBACK} = 0.4\ V \times V_{OUT(NOM)}$.

The output voltage is not regulated when the device is in current limit. When a current limit event occurs, the device begins to heat up because of the increase in power dissipation. When the device is in brickwall current limit, the pass transistor dissipates power [$(V_{IN} – V_{OUT}) \times I_{CL}$]. When the device output is shorted and the output is below $V_{FOLDBACK}$, the pass transistor dissipates power [$(V_{IN} – V_{OUT}) \times I_{SC}$]. If thermal shutdown is triggered, the device turns off. After the device cools down, the internal thermal shutdown circuit turns the device back on. If the output current fault condition continues, the device cycles between current limit and thermal shutdown. For more information on current limits, see the *Know Your Limits* application report.

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Feature Description (continued)

Figure 49 shows a diagram of the foldback current limit.

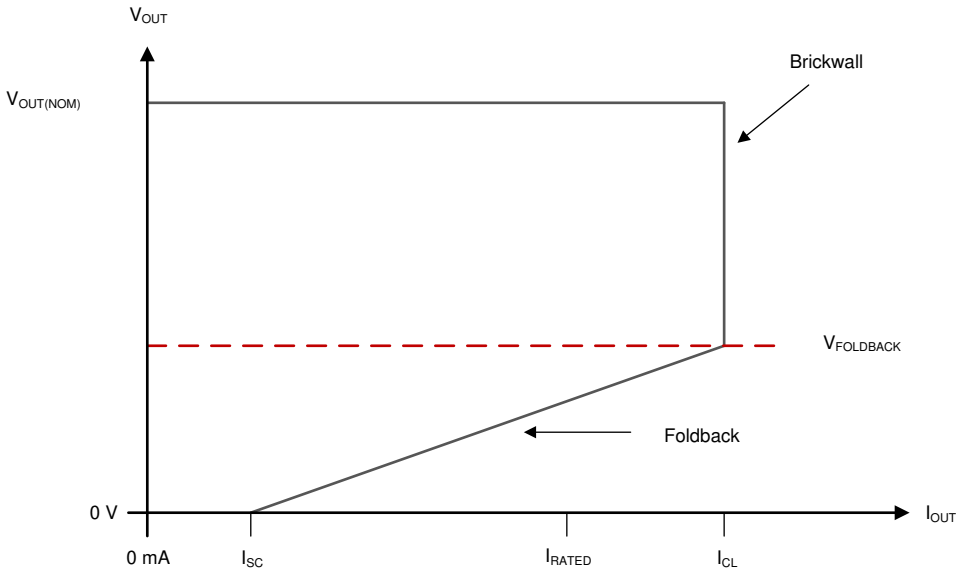


Figure 49. Foldback Current Limit

7.3.4 Thermal Shutdown

Thermal shutdown protection disables the output when the junction temperature rises to approximately 170°C. Disabling the device eliminates the power dissipated by the device, allowing the device to cool. When the junction temperature cools to approximately 155°C, the output circuitry is again enabled. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This cycling limits regulator dissipation, protecting the LDO from damage as a result of overheating.

Activating the thermal shutdown feature usually indicates excessive power dissipation as a result of the product of the (V_{IN} – V_{OUT}) voltage and the load current. For reliable operation limit junction temperature to 125°C, maximum. To estimate the margin of safety in a complete design, increase the ambient temperature until the thermal protection is triggered; use worst-case loads and signal conditions.

The TPS746-Q1 internal protection circuitry protects against overload conditions but is not intended to be activated in normal operation. Continuously running the TPS746-Q1 into thermal shutdown degrades device reliability.

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7.4 Device Functional Modes

7.4.1 Device Functional Mode Comparison

The *Device Functional Mode Comparison* table shows the conditions that lead to the different modes of operation. See the *Electrical Characteristics* table for parameter values.

Table 1. Device Functional Mode Comparison

OPERATING MODE	PARAMETER			
	V_{IN}	V_{EN}	I_{OUT}	T_J
Normal operation	$V_{IN} > V_{OUT(nom)} + V_{DO}$ and $V_{IN} > V_{IN(min)}$	$V_{EN} > V_{EN(HI)}$	$I_{OUT} < I_{OUT(max)}$	$T_J < T_{SD(shutdown)}$
Dropout operation	$V_{IN(min)} < V_{IN} < V_{OUT(nom)} + V_{DO}$	$V_{EN} > V_{EN(HI)}$	$I_{OUT} < I_{OUT(max)}$	$T_J < T_{SD(shutdown)}$
Disabled (any true condition disables the device)	$V_{IN} < V_{UVLO}$	$V_{EN} < V_{EN(LOW)}$	Not applicable	$T_J > T_{SD(shutdown)}$

7.4.2 Normal Operation

The device regulates to the nominal output voltage when the following conditions are met:

- The input voltage is greater than the nominal output voltage plus the dropout voltage ($V_{OUT(nom)} + V_{DO}$)
- The output current is less than the current limit ($I_{OUT} < I_{CL}$)
- The device junction temperature is less than the thermal shutdown temperature ($T_J < T_{SD}$)
- The enable voltage has previously exceeded the enable rising threshold voltage and has not yet decreased to less than the enable falling threshold

7.4.3 Dropout Operation

If the input voltage is lower than the nominal output voltage plus the specified dropout voltage, but all other conditions are met for normal operation, the device operates in dropout mode. In this mode, the output voltage tracks the input voltage. During this mode, the transient performance of the device becomes significantly degraded because the pass transistor is in the ohmic or triode region, and acts as a switch. Line or load transients in dropout can result in large output-voltage deviations.

When the device is in a steady dropout state (defined as when the device is in dropout, $V_{IN} < V_{OUT(NOM)} + V_{DO}$, directly after being in a normal regulation state, but *not* during startup), the pass transistor is driven into the ohmic or triode region. When the input voltage returns to a value greater than or equal to the nominal output voltage plus the dropout voltage ($V_{OUT(NOM)} + V_{DO}$), the output voltage can overshoot for a short period of time while the device pulls the pass transistor back into the linear region.

7.4.4 Disabled

The output of the device can be shutdown by forcing the voltage of the enable pin to less than the maximum EN pin low-level input voltage (see the *Electrical Characteristics* table). When disabled, the pass transistor is turned off, internal circuits are shutdown, and the output voltage is actively discharged to ground by an internal discharge circuit from the output to ground.

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8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

8.1.1 Adjustable Device Feedback Resistors

Figure 50 shows that the output voltage of the TPS746P-Q1 can be adjusted from 0.55 V to 5.5 V by using a resistor divider network.

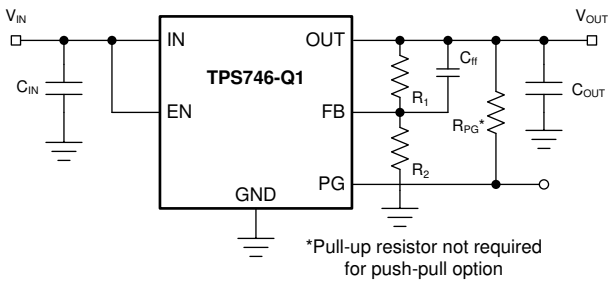


Figure 50. Adjustable Operation

The adjustable-version device requires external feedback divider resistors to set the output voltage. V_{OUT} is set using the feedback divider resistors, R_1 and R_2, according to the following equation:

$$V_{OUT} = V_{FB} \times (1 + R_1 / R_2) \quad (2)$$

To ignore the FB pin current error term in the V_{OUT} equation, set the feedback divider current to 100x the FB pin current listed in the *Electrical Characteristics* table. This setting provides the maximum feedback divider series resistance, as shown in the following equation:

$$R_1 + R_2 \leq V_{OUT} / (I_{FB} \times 100) \quad (3)$$

8.1.2 Input and Output Capacitor Selection

The TPS746-Q1 requires an output capacitance of 0.47 µF or larger for stability. Use X5R- and X7R-type ceramic capacitors because these capacitors have minimal variation in value and equivalent series resistance (ESR) over temperature. When choosing a capacitor for a specific application, pay attention to the dc bias characteristics for the capacitor. Higher output voltages cause a significant derating of the capacitor. For best performance, the maximum recommended output capacitance is 220 µF.

Although an input capacitor is not required for stability, good analog design practice is to connect a capacitor from IN to GND. Some input supplies have a high impedance, thus placing the input capacitor on the input supply helps reduce the input impedance. This capacitor counteracts reactive input sources and improves transient response, input ripple, and PSRR. If the input supply has a high impedance over a large range of frequencies, several input capacitors can be used in parallel to lower the impedance over frequency. Use a higher-value capacitor if large, fast, rise-time load transients are anticipated, or if the device is located several inches from the input power source.

8.1.3 Dropout Voltage

The TPS746-Q1 uses a PMOS pass transistor to achieve low dropout. When (V_{IN} – V_{OUT}) is less than the dropout voltage (V_{DO}), the PMOS pass device is in the linear region of operation and the input-to-output resistance is the $R_{DS(ON)}$ of the PMOS pass element. V_{DO} scales approximately with output current because the PMOS device behaves like a resistor in dropout mode. As with any linear regulator, PSRR and transient response degrade as (V_{IN} – V_{OUT}) approaches dropout operation.

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Application Information (continued)

8.1.4 Exiting Dropout

Some applications have transients that place the LDO into dropout, such as slower ramps on V_{IN} during start-up. As with other LDOs, the output may overshoot on recovery from these conditions. A ramping input supply causes an LDO to overshoot on start-up, as shown in Figure 51, when the slew rate and voltage levels are in the correct range. Use an enable signal to avoid this condition.

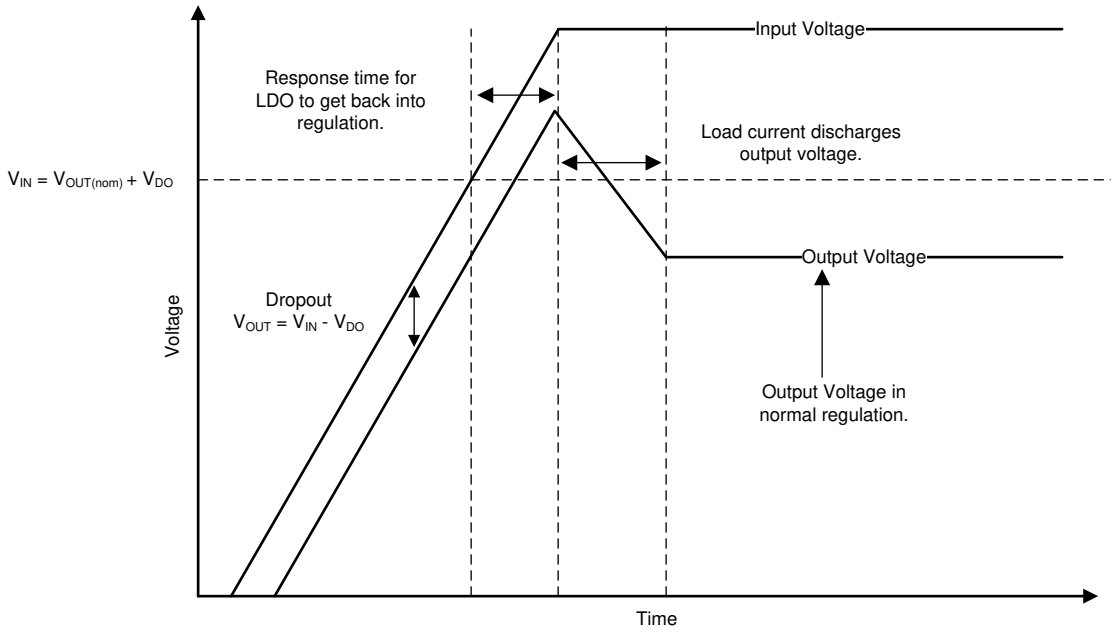


Figure 51. Startup Into Dropout

Line transients out of dropout can also cause overshoot on the output of the regulator. These overshoots are caused by the error amplifier having to drive the gate capacitance of the pass element and bring the gate back to the correct voltage for proper regulation. Figure 52 illustrates what is happening internally with the gate voltage and how overshoot can be caused during operation. When the LDO is placed in dropout, the gate voltage (VGS) is pulled all the way down to ground to give the pass device the lowest on-resistance as possible. However, if a line transient occurs when the device is in dropout, the loop is not in regulation and can cause the output to overshoot until the loop responds and the output current pulls the output voltage back down into regulation. If these transients are not acceptable, then continue to add input capacitance in the system until the transient is slow enough to reduce the overshoot.

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Application Information (continued)

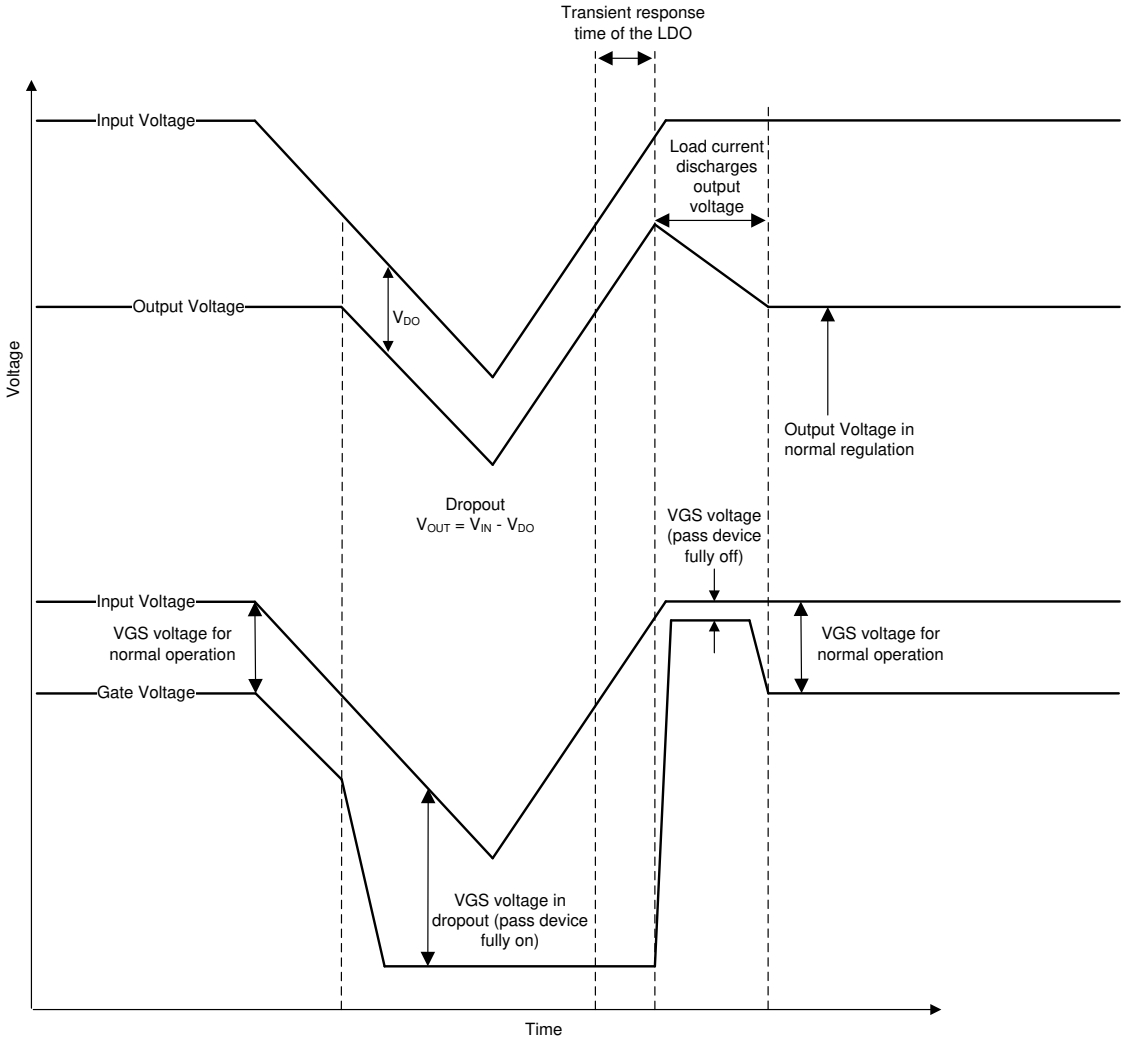


Figure 52. Line Transients From Dropout

8.1.5 Reverse Current

As with most LDOs, excessive reverse current can damage this device.

Reverse current flows through the body diode on the pass element instead of the normal conducting channel. At high magnitudes, this current flow degrades the long-term reliability of the device, as a result of one of the following conditions:

- Degradation caused by electromigration
- Excessive heat dissipation
- Potential for a latch-up condition

Conditions where reverse current can occur are outlined in this section, all of which can exceed the absolute maximum rating of $V_{OUT} > V_{IN} + 0.3$ V:

- If the device has a large C_{OUT} and the input supply collapses with little or no load current
- The output is biased when the input supply is not established
- The output is biased above the input supply

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Application Information (continued)

If reverse current flow is expected in the application, external protection must be used to protect the device. Figure 53 shows one approach of protecting the device.

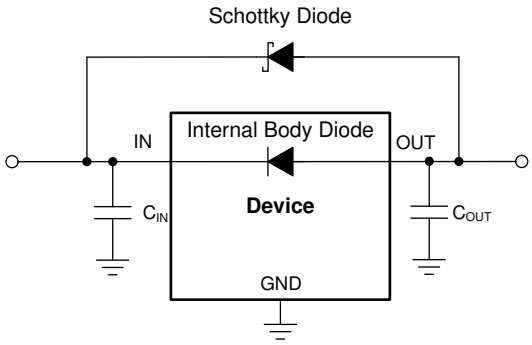


Figure 53. Example Circuit for Reverse Current Protection Using a Schottky Diode

8.1.6 Power Dissipation (P_D)

Circuit reliability requires consideration of the device power dissipation, location of the circuit on the printed circuit board (PCB), and correct sizing of the thermal plane. The PCB area around the regulator must have few or no other heat-generating devices that cause added thermal stress.

To first-order approximation, power dissipation in the regulator depends on the input-to-output voltage difference and load conditions. Equation 4 calculates power dissipation (P_D).

$$P_D = (V_{IN} – V_{OUT}) \times I_{OUT} \quad (4)$$

NOTE

Power dissipation can be minimized, and therefore greater efficiency can be achieved, by correct selection of the system voltage rails. For the lowest power dissipation use the minimum input voltage required for correct output regulation.

For devices with a thermal pad, the primary heat conduction path for the device package is through the thermal pad to the PCB. Solder the thermal pad to a copper pad area under the device. This pad area must contain an array of plated vias that conduct heat to additional copper planes for increased heat dissipation.

The maximum power dissipation determines the maximum allowable ambient temperature (T_A) for the device. According to Equation 5, power dissipation and junction temperature are most often related by the junction-to-ambient thermal resistance ($R_{\theta JA}$) of the combined PCB and device package and the temperature of the ambient air (T_A).

$$T_J = T_A + (R_{\theta JA} \times P_D) \quad (5)$$

Thermal resistance ($R_{\theta JA}$) is highly dependent on the heat-spreading capability built into the particular PCB design, and therefore varies according to the total copper area, copper weight, and location of the planes. The junction-to-ambient thermal resistance listed in the *Thermal Information* table is determined by the JEDEC standard PCB and copper-spreading area, and is used as a relative measure of package thermal performance.

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Application Information (continued)

Figure 54 and Figure 55 show the functions of $R_{\theta JA}$ and ψ_{JB} versus copper area and thickness. These plots are generated with a 101.6-mm × 101.6-mm × 1.6-mm PCB of two and four layers. For the four layer board, the inner planes use 1-oz copper thickness. Outer layers are simulated with both 1-oz and 2-oz copper thickness. A 2 x 1 array of thermal vias of 300-µm drill diameter and 25-µm copper (Cu) plating is located beneath the thermal pad of the device. The thermal vias connect the top layer, the bottom layer and, in the case of the 4-layer board, the first inner GND plane. Each of the layers has a copper plane of equal area, as shown in Figure 56.

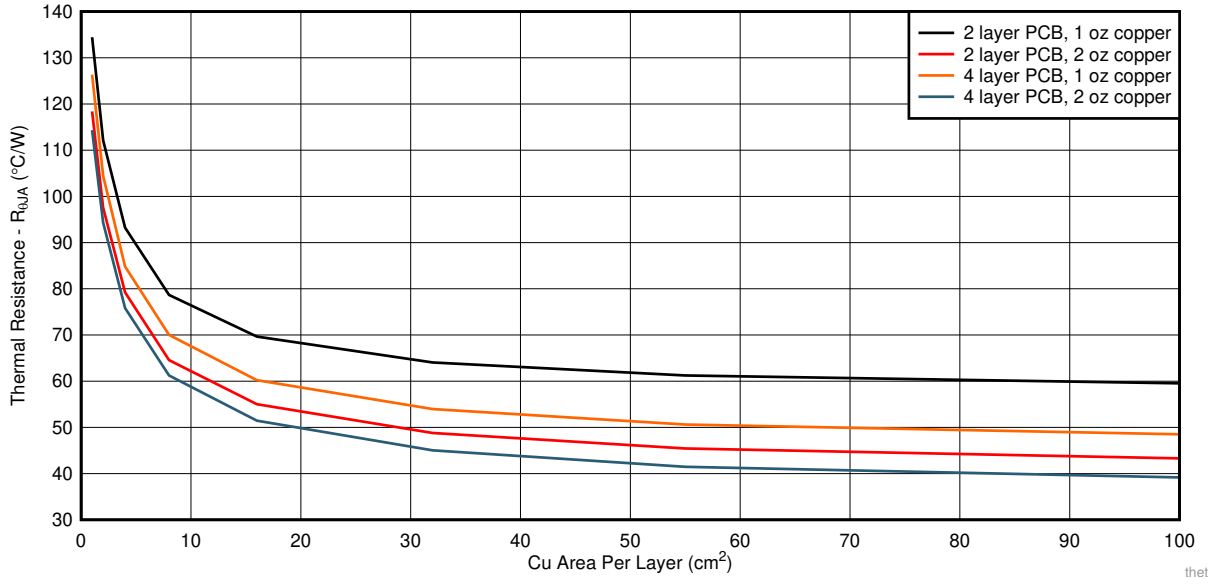


Figure 54. $R_{\theta JA}$ versus Cu Area for the WSON (DRV) Package

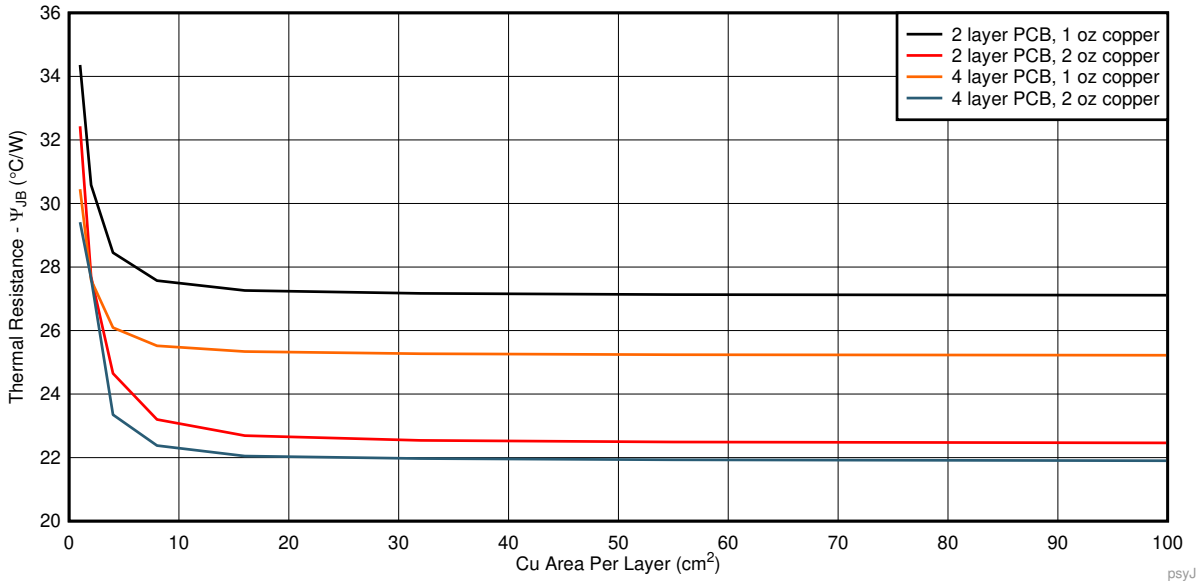
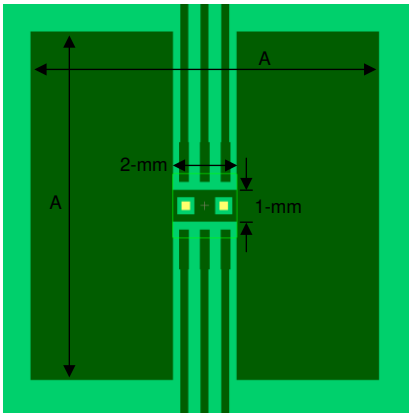


Figure 55. ψ_{JB} versus Cu Area for the WSON (DRV) Package

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Application Information (continued)

As shown in Figure 56, each of the layers has a copper plane of equal area.



Buried plane and bottom layer Cu ground planes are modeled with Area = A×A

Figure 56. Board Parameters Used for Simulation

For a more comprehensive study of how thermal resistance varies with copper area and thickness, see the *An Empirical Analysis of the Impact of Board Layout on LDO Thermal Performance* application report. As shown in Figure 57, modifying board layout to be more thermally enhanced can lower the $R_{\theta JA}$ value from 80.3ºC/W to 46.8ºC/W or better.

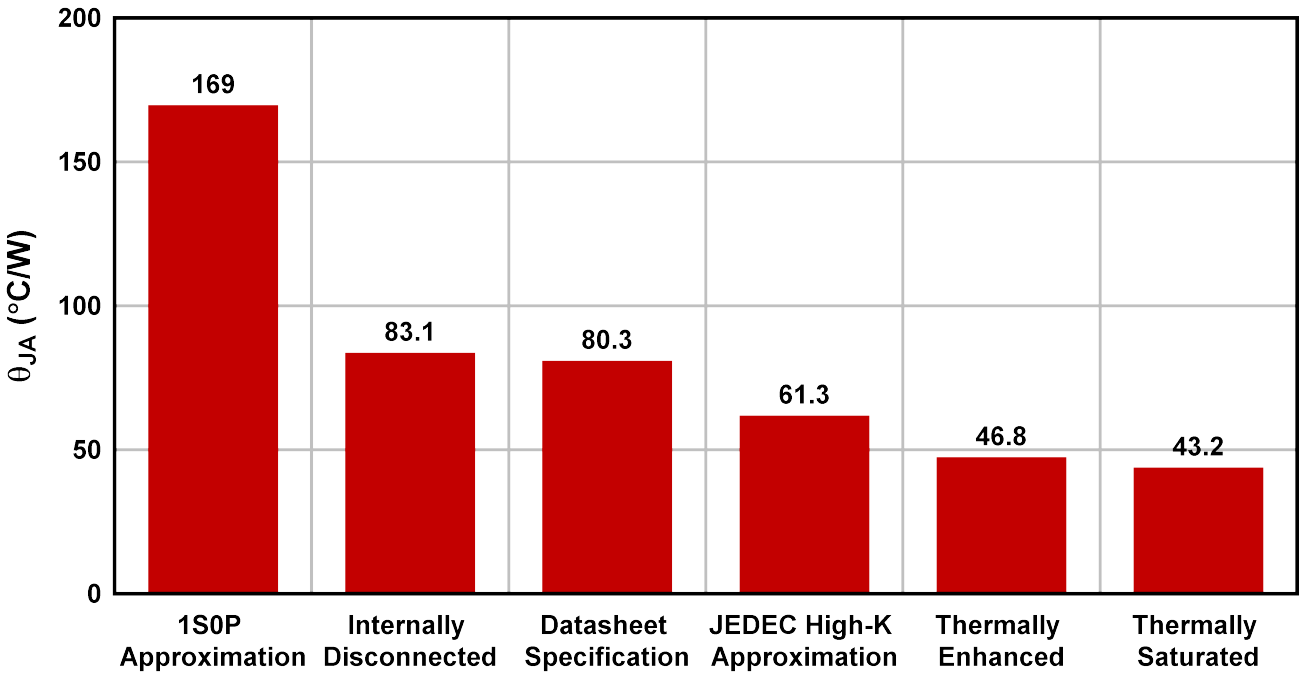


Figure 57. TPS746-Q1 (WSON) $R_{\theta JA}$ vs Board Layout

Application Information (continued)

8.1.7 Power-Good Function

The power-good circuit monitors the voltage at the feedback pin to indicate the status of the output voltage. When the output voltage falls below the PG threshold voltage (PG_{LTH}), the PG pin open-drain output engages and pulls the PG pin close to GND. When the output voltage exceeds PG_{HTH}, the PG pin becomes high impedance. The open-drain output requires a pullup resistor. By connecting a pullup resistor to an external supply, any downstream device can receive power-good as a logic signal that can be used for sequencing. Additionally, the open-drain output can be tied to other open-drain outputs to implement AND logic. Make sure that the external pullup supply voltage results in a valid logic signal for the receiving device. Using a pullup resistor from 10 kΩ to 100 kΩ is recommended. The push-pull power-good output option does not require the pullup resistor and instead has a high logic signal that correlates with the output voltage of the device. The push-pull option is supported only for $V_{OUT} \geq 1.0$ V. Do not tie the push-pull output to other logic outputs.

When using a feed-forward capacitor (C_{FF}), the time constant for the LDO startup is increased whereas the power-good output time constant stays the same, possibly resulting in an invalid status of the power-good output. To avoid this issue, and to receive a valid PG output, make sure that the time constant of both the LDO startup and the power-good output match, which can be done by adding a capacitor in parallel with the power-good pullup resistor. For more information, see the *Pros and Cons of Using a Feedforward Capacitor with a Low-Dropout Regulator* application report.

The state of PG is only valid when the device operates above the minimum input voltage of the device and power-good is asserted, regardless of the output voltage state when the input voltage falls below the UVLO threshold minus the UVLO hysteresis. When the input voltage falls below approximately 0.8 V, there is not enough gate drive voltage to keep the open-drain, power-good device turned on and the power-good output pulled high. Connecting the power-good pullup resistor to the output voltage can help minimize this effect.

8.1.8 Feed-Forward Capacitor (C_{FF})

For the adjustable-voltage version device, a feed-forward capacitor (C_{FF}) can be connected from the OUT pin to the FB pin. C_{FF} improves transient, noise, and PSRR performance, but is not required for regulator stability. Recommended C_{FF} values are listed in the *Recommended Operating Conditions* table. A higher capacitance C_{FF} can be used; however, the startup time increases. For a detailed description of C_{FF} tradeoffs, see the *Pros and Cons of Using a Feedforward Capacitor with a Low-Dropout Regulator* application report.

8.1.9 Start-Up Sequencing

If V_{EN} is greater than V_{UVLO} rising (min), the input pin (IN) must sink 1 mA of current to avoid the device being turned on with a floating input pin.

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8.2 Typical Application

Figure 58 shows the typical application circuit for the TPS746P-Q1. Input and output capacitances must be at least 1 µF.

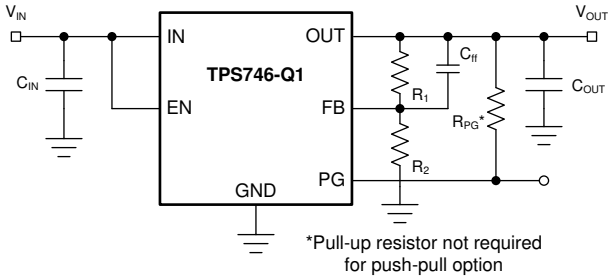


Figure 58. TPS746-Q1 Typical Application

8.2.1 Design Requirements

Use the parameters listed in Table 2 for typical linear regulator applications.

Table 2. Design Parameters

PARAMETER	DESIGN REQUIREMENT
Input voltage	3.8 V
Output voltage	3.3 V, ±1%
Input current	1.2 A (maximum)
Output load	1-A DC
Maximum ambient temperature	70°C

8.2.2 Detailed Design Procedure

Input and output capacitors are required to achieve the output voltage transient requirements. Capacitance values of 2.2 µF are selected to give the maximum output capacitance in a small, low-cost package; see the *Input and Output Capacitor Selection* section for details.

Figure 50 illustrates the output voltage of the TPS746-Q1. Set the output voltage using the resistor divider; see the *Adjustable Device Feedback Resistors* section for details.

8.2.2.1 Input Current

During normal operation, the input current to the LDO is approximately equal to the output current of the LDO. During startup, the input current is higher as a result of the inrush current charging the output capacitor. Use Equation 6 to calculate the current through the input.

$$I_{OUT(t)} = \left[\frac{C_{OUT} \times dV_{OUT}(t)}{dt}\right] + \left[\frac{V_{OUT}(t)}{R_{LOAD}}\right]$$

where:

- $V_{OUT}(t)$ is the instantaneous output voltage of the turn-on ramp
- $dV_{OUT}(t) / dt$ is the slope of the V_{OUT} ramp
- R_{LOAD} is the resistive load impedance (6)

8.2.2.2 Thermal Dissipation

The junction temperature can be determined using the junction-to-ambient thermal resistance ($R_{\theta JA}$) and the total power dissipation (P_D). Use Equation 7 to calculate the power dissipation. Multiply P_D by $R_{\theta JA}$ as Equation 8 shows and add the ambient temperature (T_A) to calculate the junction temperature (T_J).

$$P_D = (I_{GND} + I_{OUT}) \times (V_{IN} - V_{OUT}) \quad (7)$$

$$T_J = R_{\theta JA} \times P_D + T_A \quad (8)$$

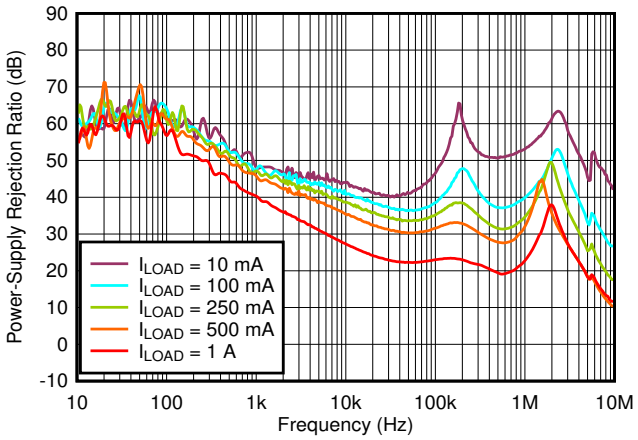
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Calculate the maximum ambient temperature as Equation 9 shows if the ($T_{J(MAX)}$) value does not exceed 125°C. Equation 10 calculates the maximum ambient temperature with a value of 109.85°C.

$$T_{A(MAX)} = T_{J(MAX)} – R_{\theta JA} \times P_D \quad (9)$$

$$T_{A(MAX)} = 150°C – 80.3°C/W \times (3.8\ V – 3.3\ V) \times (1\ A) = 109.85°C \quad (10)$$

8.2.3 Application Curve



V_{IN} = 3.8 V, V_{OUT} = 3.3 V, C_{OUT} = 2.2 µF

Figure 59. PSRR vs Frequency and I_{LOAD}

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9 Power Supply Recommendations

The TPS745-Q1 is designed to operate from an input voltage supply range from 1.5 V to 6.0 V. The input voltage range provides adequate headroom in order for the device to have a regulated output. This input supply must be well regulated. If the input supply is noisy, additional input capacitors with low ESR may help improve output noise performance. Connect a low output impedance power supply directly to the IN pin of the TPS746-Q1.

10 Layout

10.1 Layout Guidelines

- Place input and output capacitors as close to the device as possible.
- Use copper planes for device connections in order to optimize thermal performance.
- Place thermal vias around the device to distribute heat.
- Place a tented thermal via directly beneath the thermal pad of the DRV or DRB package. An untented via can wick solder or solder paste away from the thermal pad joint during the soldering process, leading to a compromised solder joint on the thermal pad.

10.2 Layout Examples

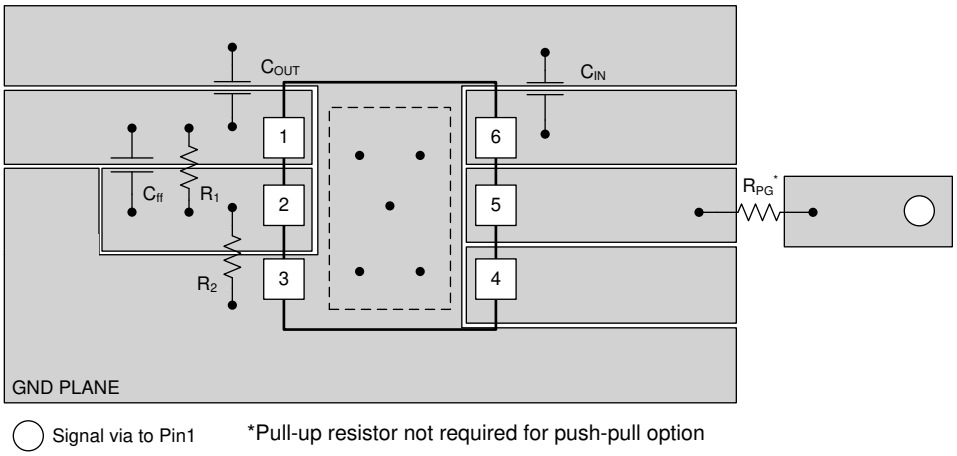


Figure 60. Layout Example for the DRV Package

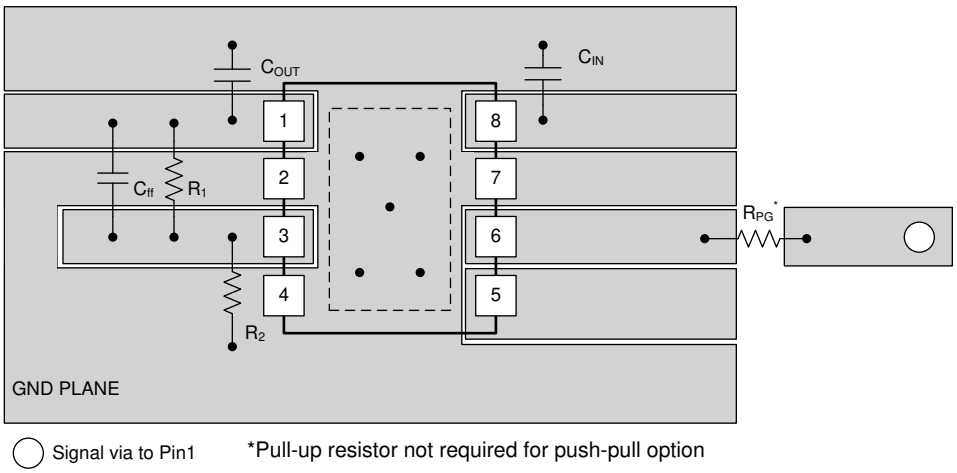


Figure 61. Layout Example for the DRB package

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11 Device and Documentation Support

11.1 Device Support

11.1.1 Device Nomenclature

Table 3. Device Nomenclature(1)(2)

PRODUCT	V_{OUT}
TPS746)**xx(x)PvQWyyyzQ1**	**xx(x)** is the nominal output voltage. For output voltages with a resolution of 100 mV, two digits are used in the ordering number; otherwise, three digits are used (for example, 28 = 2.8 V; 125 = 1.25 V; 01 = adjustable). **P** indicates an active output discharge feature. All members of the TPS746 family will actively discharge the output when the device is disabled. **v** indicates the topology of the power-good output and the timing associated with the power-good delay. • If unused, indicates an open-drain power-good output with a 150-µs delay. • If **B**, indicates an open-drain, power-good output with a 5-ms delay. • If **C**, indicates a push-pull, power-good output with a 150-µs delay. **Q** indicates that this device is a Grade-1 device in accordance with the AEC-Q100 standard. **W** indicates the package has wettable flanks. **yyy** is the package designator. **z** is the package quantity. R is for reel (3000 pieces). **Q1** indicates that this device is an automotive grade (AEC-Q100) device.

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or visit the device product folder on www.ti.com.
(2) Output voltages from 0.65 V to 5.0 V in 50-mV increments are available. Contact the factory for details and availability.

11.2 Documentation Support

11.2.1 Related Documentation

For related documentation see the following:

- Texas Instruments, *Pros and Cons of Using a Feedforward Capacitor with a Low-Dropout Regulator* application report
- Texas Instruments, *An Empirical Analysis of the Impact of Board Layout on LDO Thermal Performance* application report

11.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.4 Community Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

11.5 Trademarks

E2E is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

11.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

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11.7 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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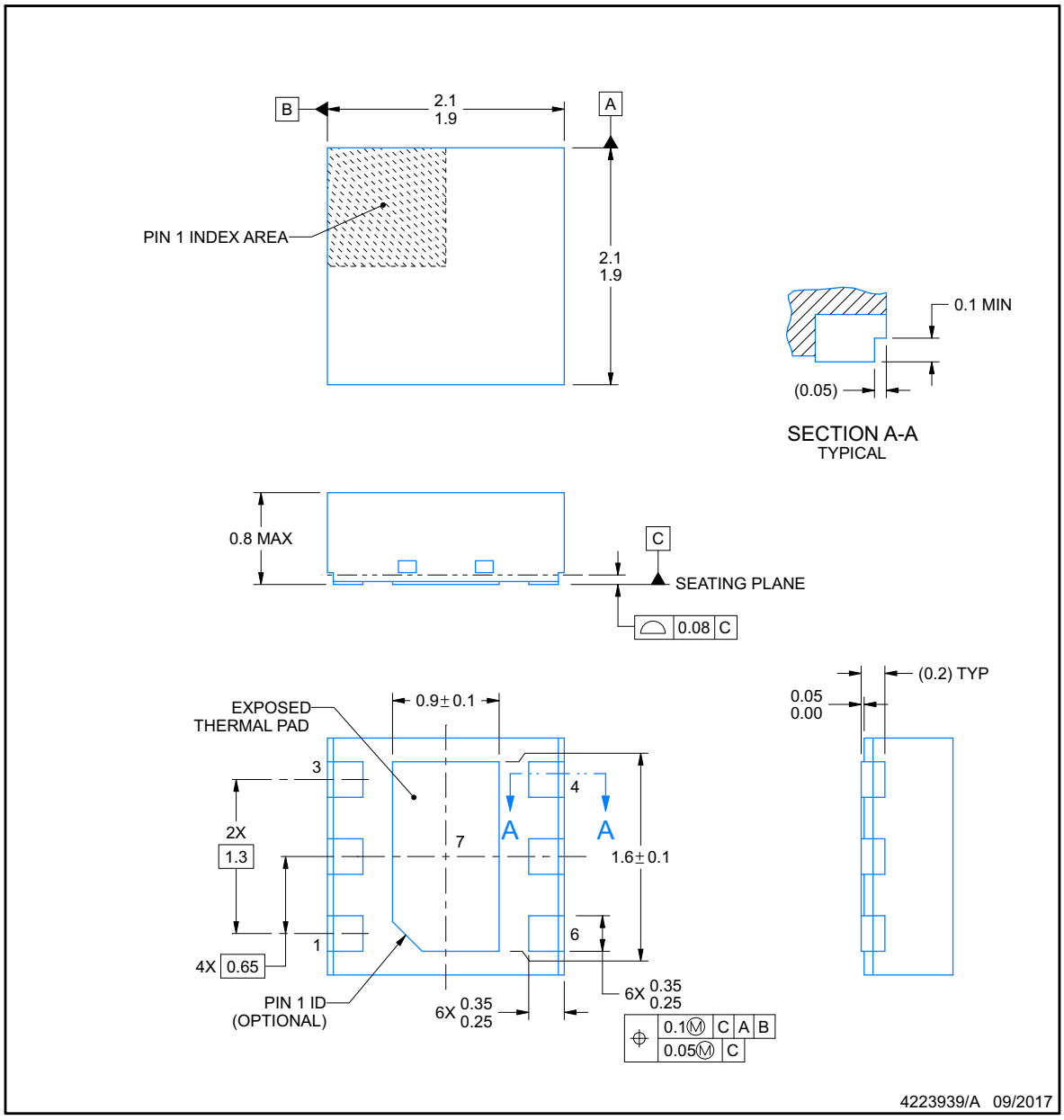
PACKAGE OUTLINE

DRV0006C



WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

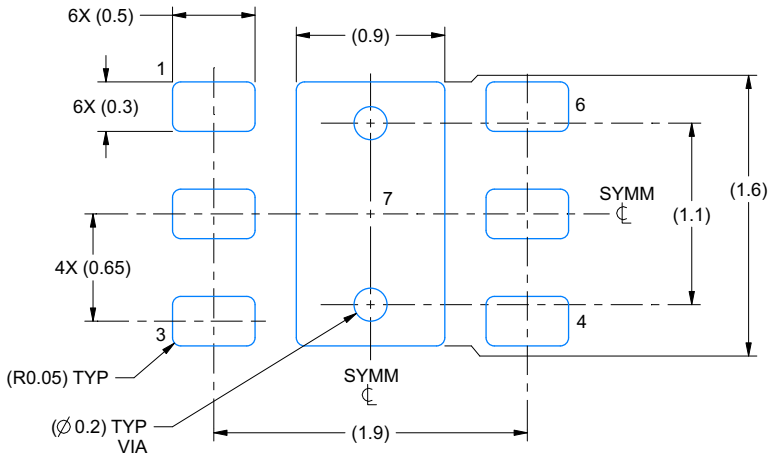
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EXAMPLE BOARD LAYOUT

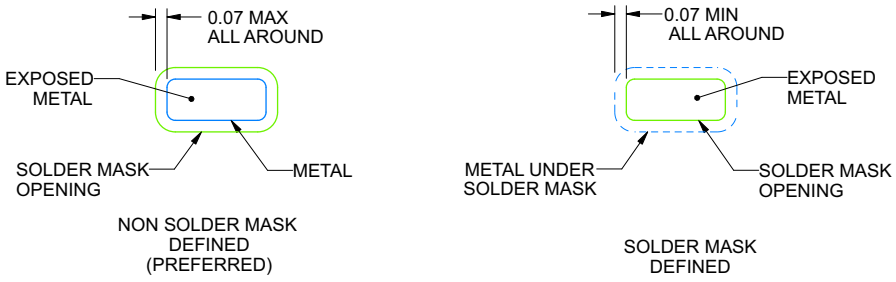
DRV0006C

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:25X



SOLDER MASK DETAILS

4223939/A 09/2017

NOTES: (continued)

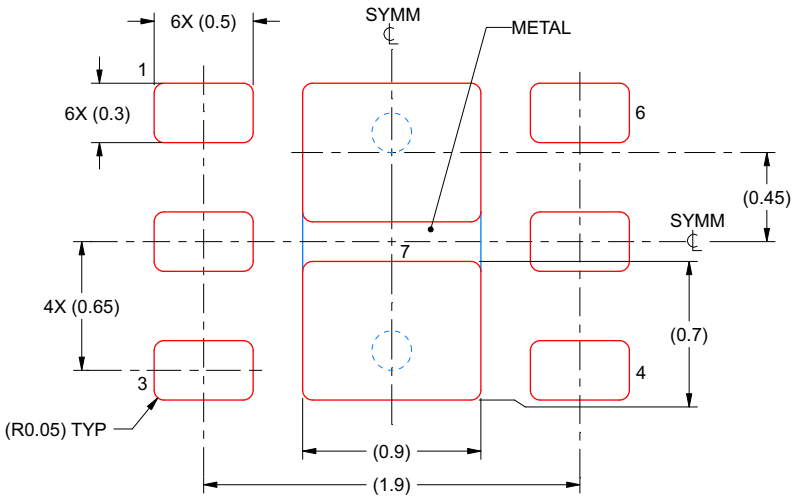
3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
4. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

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EXAMPLE STENCIL DESIGN

DRV0006C — **WSON - 0.8 mm max height**

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD #7:
88% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:30X

4223939/A 09/2017

NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

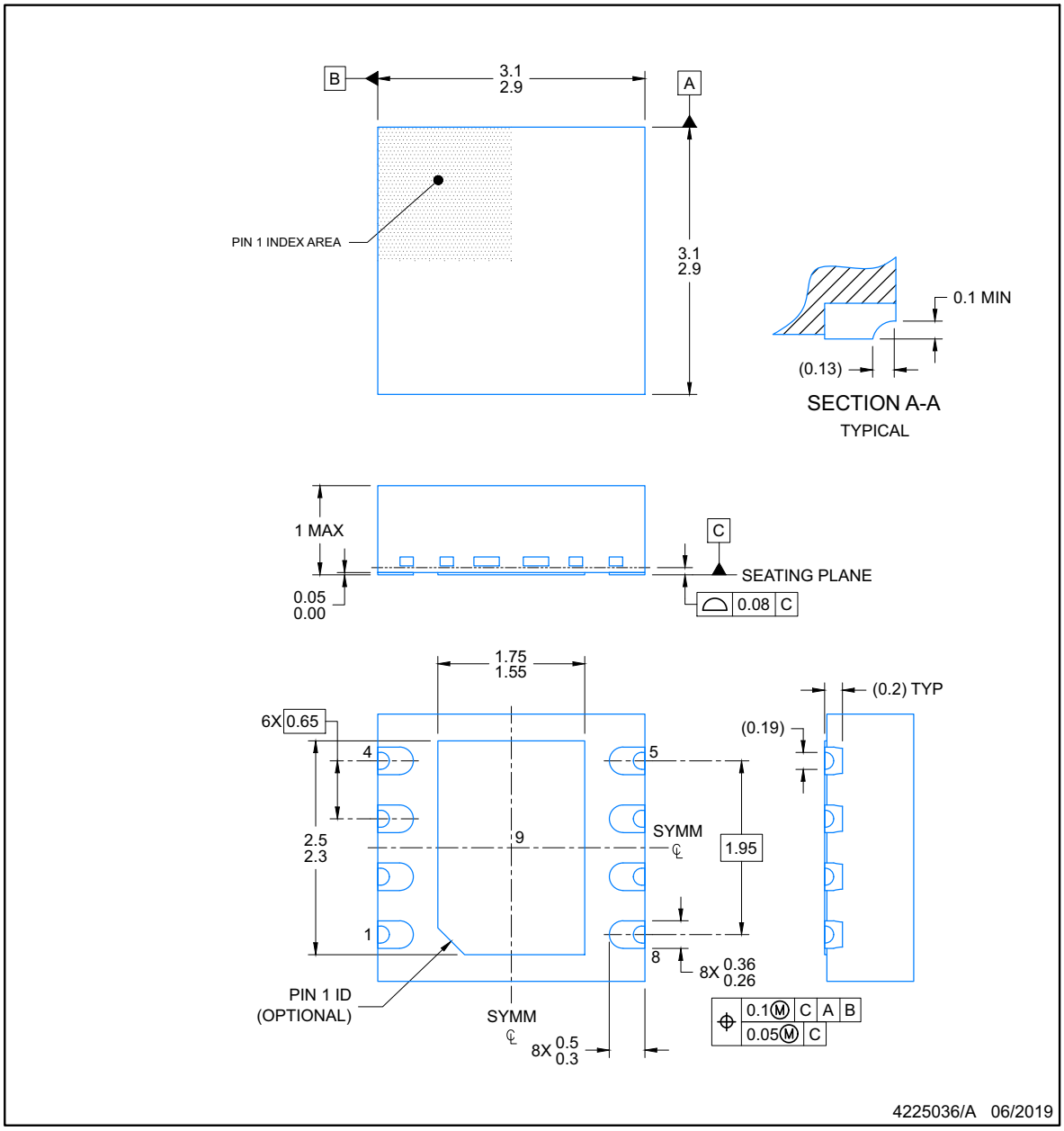
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PACKAGE OUTLINE

DRB0008J

VSON - 1 mm max height

PLASTIC QUAD FLAT PACK- NO LEAD



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.

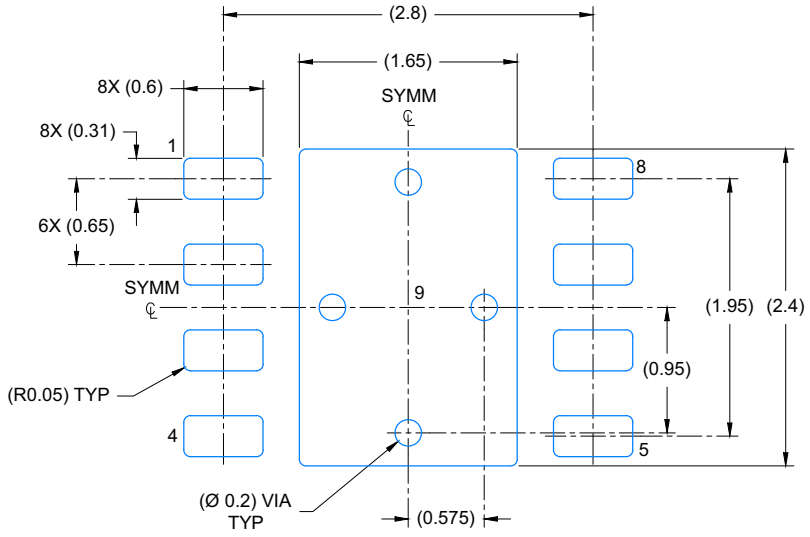
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EXAMPLE BOARD LAYOUT

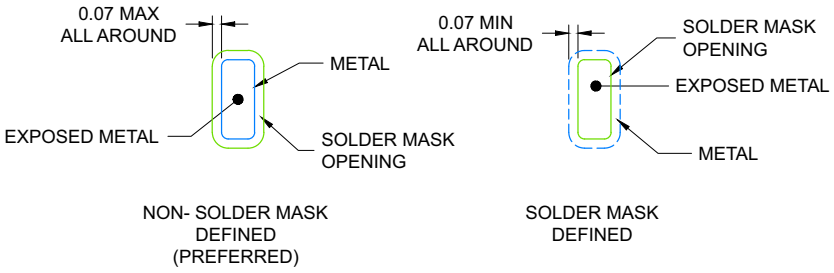
DRB0008J

VSON - 1 mm max height

PLASTIC QUAD FLAT PACK- NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 20X



SOLDER MASK DETAILS

4225036/A 06/2019

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

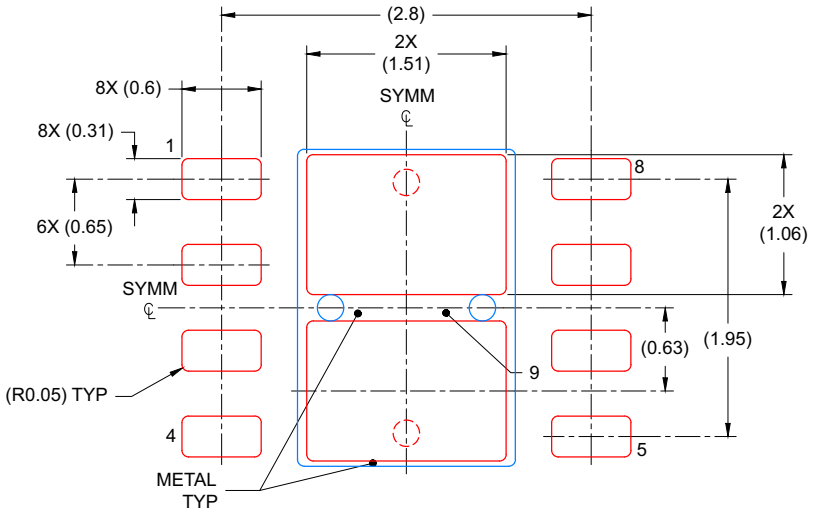
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EXAMPLE STENCIL DESIGN

DRB0008J

VSON - 1 mm max height

PLASTIC QUAD FLAT PACK- NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD
81% PRINTED COVERAGE BY AREA
SCALE: 20X

4225036/A 06/2019

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
PPS74601PQWDRBRQ1	ACTIVE	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 125		Samples
PPS74610PQWDRBRQ1	ACTIVE	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 150		Samples
PPS74611PQWDRBRQ1	ACTIVE	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 150		Samples
PPS74612PQWDRBRQ1	ACTIVE	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 150		Samples
PPS74618PQWDRBRQ1	ACTIVE	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 150		Samples
PPS74633PQWDRBRQ1	ACTIVE	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 150		Samples
TPS74601PBQWDRVRQ1	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM	-40 to 125	1S46	Samples
TPS74601PCQWDRVRQ1	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM	-40 to 125	1OZ6	Samples
TPS74601PQWDRBRQ1	PREVIEW	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 125		
TPS74601PQWDRVRQ1	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	SN	Level-1-260C-UNLIM	-40 to 125	1OW6	Samples
TPS74607PQWDRBRQ1	PREVIEW	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 125		
TPS74610PQWDRBRQ1	PREVIEW	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 125		
TPS74610PQWDRVRQ1	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	SN	Level-1-260C-UNLIM	-40 to 125	1SG6	Samples
TPS74611PQWDRBRQ1	PREVIEW	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 125		
TPS74611PQWDRVRQ1	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	SN	Level-1-260C-UNLIM	-40 to 125	1SH6	Samples
TPS746125PQWDRBRQ1	PREVIEW	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 125		
TPS74612PQWDRBRQ1	PREVIEW	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 125		
TPS74612PQWDRVRQ1	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	SN	Level-1-260C-UNLIM	-40 to 125	1SI6	Samples
TPS74615PQWDRBRQ1	PREVIEW	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 125		
TPS74615PQWDRVRQ1	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	SN	Level-1-260C-UNLIM	-40 to 125	1SJ6	Samples
TPS74617PQWDRBRQ1	PREVIEW	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 125		

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS74618PQWDRBRQ1	PREVIEW	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 125		
TPS74618PQWDRVRQ1	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	SN	Level-1-260C-UNLIM	-40 to 125	1SK6	Samples
TPS74625PQWDRBRQ1	PREVIEW	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 125		
TPS74625PQWDRVRQ1	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	SN	Level-1-260C-UNLIM	-40 to 125	1SL6	Samples
TPS74628PQWDRBRQ1	PREVIEW	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 125		
TPS74628PQWDRVRQ1	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	SN	Level-1-260C-UNLIM	-40 to 125	1SM6	Samples
TPS74629PQWDRBRQ1	PREVIEW	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 125		
TPS74629PQWDRVRQ1	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	SN	Level-1-260C-UNLIM	-40 to 125	1SN6	Samples
TPS74630PQWDRBRQ1	PREVIEW	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 125		
TPS74633PCQWDRVRQ1	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM	-40 to 125	1P16	Samples
TPS74633PQWDRBRQ1	PREVIEW	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 125		
TPS74633PQWDRVRQ1	ACTIVE	WSON	DRV	6	3000	Green (RoHS & no Sb/Br)	SN	Level-1-260C-UNLIM	-40 to 125	1OX6	Samples
TPS74650PQWDRBRQ1	PREVIEW	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 125		

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF TPS746-Q1 :

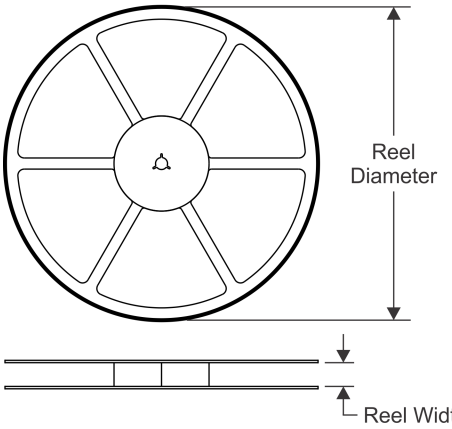
- Catalog: TPS746

NOTE: Qualified Version Definitions:

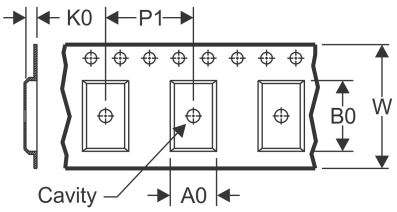
- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION

REEL DIMENSIONS

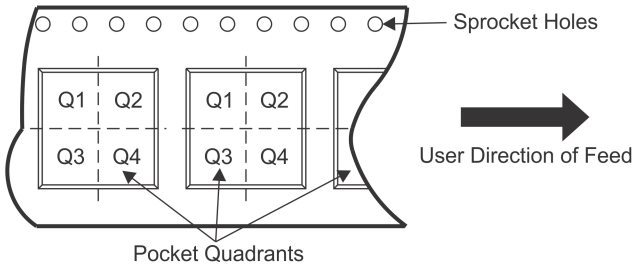


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

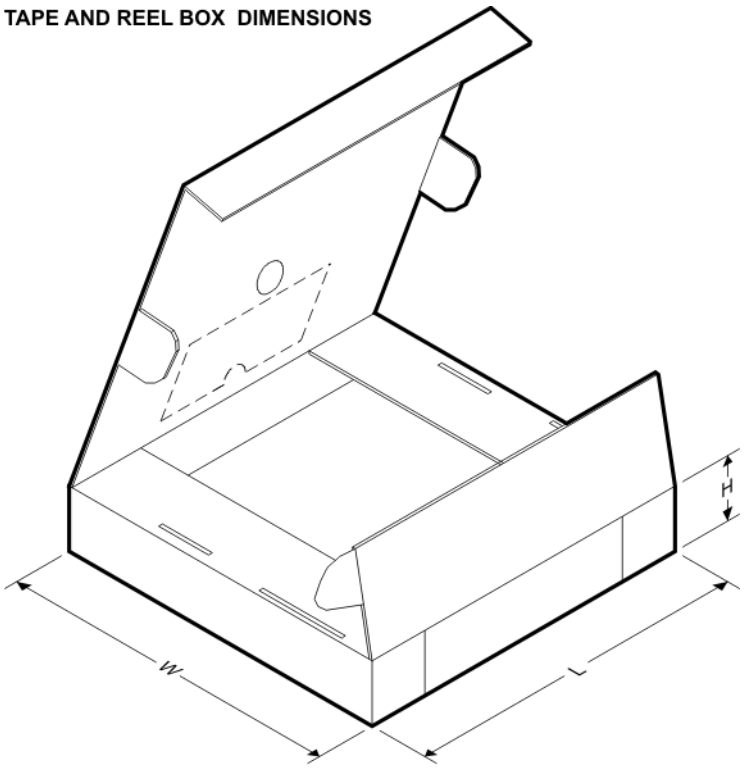
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS74601PBQWDRVRQ1	WSON	DRV	6	3000	180.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS74601PCQWDRVRQ1	WSON	DRV	6	3000	180.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS74601PQWDRVRQ1	WSON	DRV	6	3000	180.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS74610PQWDRVRQ1	WSON	DRV	6	3000	180.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS74611PQWDRVRQ1	WSON	DRV	6	3000	180.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS74612PQWDRVRQ1	WSON	DRV	6	3000	180.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS74615PQWDRVRQ1	WSON	DRV	6	3000	180.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS74618PQWDRVRQ1	WSON	DRV	6	3000	180.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS74625PQWDRVRQ1	WSON	DRV	6	3000	180.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS74628PQWDRVRQ1	WSON	DRV	6	3000	180.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS74629PQWDRVRQ1	WSON	DRV	6	3000	180.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS74633PCQWDRVRQ1	WSON	DRV	6	3000	180.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS74633PQWDRVRQ1	WSON	DRV	6	3000	180.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2

TAPE AND REEL BOX DIMENSIONS

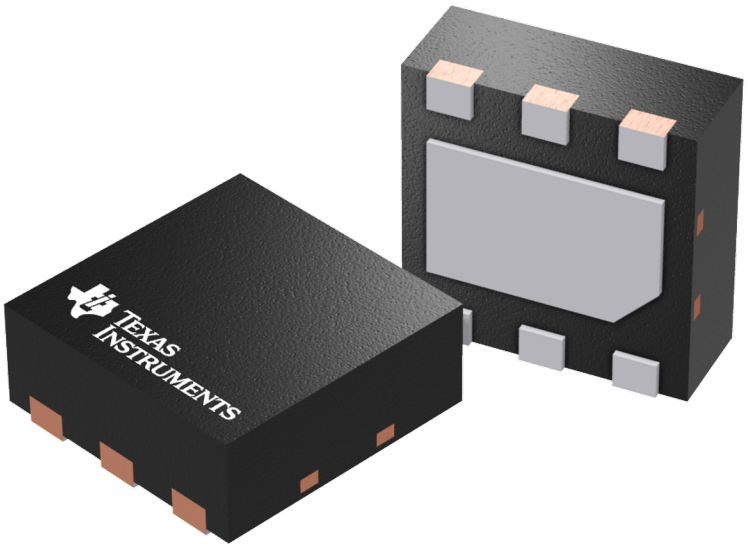


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS74601PBQWDRVRQ1	WSON	DRV	6	3000	203.0	203.0	35.0
TPS74601PCQWDRVRQ1	WSON	DRV	6	3000	203.0	203.0	35.0
TPS74601PQWDRVRQ1	WSON	DRV	6	3000	203.0	203.0	35.0
TPS74610PQWDRVRQ1	WSON	DRV	6	3000	203.0	203.0	35.0
TPS74611PQWDRVRQ1	WSON	DRV	6	3000	203.0	203.0	35.0
TPS74612PQWDRVRQ1	WSON	DRV	6	3000	203.0	203.0	35.0
TPS74615PQWDRVRQ1	WSON	DRV	6	3000	203.0	203.0	35.0
TPS74618PQWDRVRQ1	WSON	DRV	6	3000	203.0	203.0	35.0
TPS74625PQWDRVRQ1	WSON	DRV	6	3000	203.0	203.0	35.0
TPS74628PQWDRVRQ1	WSON	DRV	6	3000	203.0	203.0	35.0
TPS74629PQWDRVRQ1	WSON	DRV	6	3000	203.0	203.0	35.0
TPS74633PCQWDRVRQ1	WSON	DRV	6	3000	203.0	203.0	35.0
TPS74633PQWDRVRQ1	WSON	DRV	6	3000	203.0	203.0	35.0

DRV 6 WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

GENERIC PACKAGE VIEW

DRB 8

VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4203482/L

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